

Cite this: *Nanoscale Adv.*, 2022, 4, 3537

Quantification and removal of carbonaceous impurities in a surfactant-assisted carbon nanotube dispersion and its implication on electronic properties†

Minsuk Park, In-Seung Choi and Sang-Yong Ju *

Carbonaceous impurities (CIs) affect the optoelectronic properties as well as the ability to use absorption spectroscopy to estimate the metallic content of a single-walled carbon nanotube (SWNT) dispersion. Therefore, a method for the accurate quantification and removal of CIs is required. We have devised methods to characterize and quantify CIs present in SWNT batches and to determine the effects of CIs on the optical and electrical properties of SWNT. Quantitative determination of CIs stems from the finding that chloroform selectively disperses CIs present in SWNT batches. CIs separated by dispersing the as-purchased SWNT batch in chloroform have the morphology of defective and agglomerated few-layered graphenes, whose sizes and locations depend on SWNT batches. Moreover, CIs exhibit a featureless UV-vis-mid-wavelength IR (MWIR) absorption curve and an extinction coefficient comparable to graphenes and show difference with carbon black, which is frequently used as the CI reference. The MWIR region that shows least absorptions caused by the transition of various SWNT types was utilized to assess the significant contribution made by CIs present in a surfactant-assisted SWNT dispersion, showing about 12–19 wt% of CIs in various SWNT dispersions. In addition, the extraction of CIs with chloroform results in a highly purified SWNT batch without any diameter distribution change originating from oxidative damage as compared to the commercially available purified SWNT batch. Finally, we found that increasing the weight of CIs present in a SWNT dispersion strongly lowers the thermal conductivity of a SWNT film when compared with the electrical conductivity. This study provides a way to understand the negative effects that CI has on the optoelectronic properties of SWNTs as well as the beneficial effects of excluding ubiquitous CIs in SWNTs batches.

Received 12th March 2022

Accepted 10th June 2022

DOI: 10.1039/d2na00153e

rsc.li/nanoscale-advances

1. Introduction

Single-walled carbon nanotubes (SWNTs) with defined electrical properties are optimal materials for next-generation optoelectronic devices. Semiconducting (s)-SWNTs are especially interesting because they have excellent electrical properties including high current on/off ratios exceeding 10^6 and charge carrier mobility.^{1–5} Owing to their unique features, s-SWNTs have broad solution-based applications in thin film transistors,^{1–5} thermoelectric devices,^{6–8} and photovoltaic devices.^{9–11} The SWNT batch contains SWNTs, carbonaceous impurities (CIs) and metal catalysts, among which the metal catalysts possessing metals inside graphitic shells can be easily removed by centrifugation owing to their density.¹⁶ Despite these potential impacts, SWNTs suffer from heterogeneity issues associated with the presence of CIs^{12,13} formed as byproducts during SWNT growth and serves as an obstacle for high-end optoelectronic applications.

The CI has a metallic property originating from the graphitic structure of several layers with a size of several tens of nanometers. These structural characteristics promote the adsorption

Department of Chemistry, Yonsei University, 50 Yonsei-ro, Seodaemun-Gu, Seoul 03722, Republic of Korea. E-mail: syju@yonsei.ac.kr; Tel: +82-2-2123-5639

† Electronic supplementary information (ESI) available: Absorption cross section calculation of monolayer graphene, defect density calculations of CI and CB, assignment of FT-IR bands absorption spectra comparison of CI, UV-vis-MWIR absorption spectrum of CI containing chloroform dispersion (Fig. S1), absorption spectra comparison of CI dispersion in chloroform, CB, and graphene (Fig. S2), TEM and SEM images of CI dispersion in chloroform (Fig. S3), CI-subtracted absorption spectrum of FC12-PSWNT dispersion (Fig. S4), UV-vis-FIR absorption spectra of FC12 dispersions in *p*-xylene (Fig. S5), AFM height images of acetone-washed HiPco, PSWNT, and LDSWNT (Fig. S6), absorption spectra of vigorous chloroform dispersions (Fig. S7), atomic contents of PSWNT, acetone-washed PSWNT and CI (Fig. S8), TGA thermograms (Fig. S9), overall wt. including CI/SWNT and net SWNT purity (Fig. S10), overlaid CI-subtracted net PSWNT spectra (Fig. S11), comparison of AFM-based number of CI per SWNT length (Fig. S12), configuration of prepatterned chip for σ and κ measurements (Fig. S13), photographs of the transferred PSWNT films on prepatterned chips (Fig. S14), CI-added FC12-PSWNT dispersions (Fig. S15) and thickness changes of PSWNT film on a quartz substrate by a surface profiler (Fig. S16) are provided. This material is available free of charge via the Internet. See <https://doi.org/10.1039/d2na00153e>

of CIs onto the surface of SWNTs, which form aggregates themselves, making it difficult to distinguish them from SWNTs.^{14,15} In particular, metallic CIs act as scatters for electric charge conduction and heat transfer through SWNTs, thereby lowering intrinsic properties¹⁵ and interfering with SWNT signals in electrochemical reactions.¹⁶ For this reason, many efforts are made to remove CIs, and one of them is the method of removing CIs *via* oxidation. However, this removal method makes the price several orders of magnitude more expensive¹⁷ and has the disadvantage of generating oxidation defects¹⁸ by reacting structurally similar SWNTs.

With the development of the technology for separating *s*-SWNTs from the dispersion phase,^{19–22} the analysis method for CIs present in the solution phase is also an important factor in making pure *s*-SWNTs. Among various CI analysis methods,^{23–25} the absorption of the CI is thought to be the most suitable method for its quantification since the metallic nature of the CI is expected to be featureless absorption, which is clear departure from the absorption peak form resulting from one-dimensional van Hove singularity (vHs) of SWNTs. However, since there is no method to selectively extract only CIs from SWNTs, carbon black (CB) that has a globular graphitic structure is used to define the background absorption instead, leading to large variations. Especially, a greater deviation occurs while quantifying impurities in *s*-enriched SWNT dispersions with a high purity of 90% or more. For this reason, purity evaluation methods of *s*-SWNTs using Raman mapping²⁶ or thin film transistors²⁷ have been proposed. Therefore, there is a need for a method capable of precisely analyzing the content of CIs in the SWNT dispersion in the solution phase.

In the study described below, we developed a method for the quantification of CIs in a SWNT dispersion. The properties of the CI were characterized by various methods including absorption spectroscopy, transmission electron microscopy (TEM), scanning electron microscopy (SEM) and Raman spectroscopy. The effect of the CI on an SWNT dispersion prepared using a *N*-dodecyl flavin surfactant (FC12) was investigated by UV-vis-mid-wavelength IR (MWIR) absorption spectroscopy. Furthermore, we observed that chloroform can be employed to disperse only the CI component in the as-prepared SWNT, leaving the pure SWNT as a precipitate, and the degree of CI extraction depends on its morphology. This selected dispersion technique provides a framework for deconvoluting contributions by CIs to the absorption spectrum, gravimetric and thermal analysis, and purity of the as-prepared SWNT. The CI-excluded absorption spectrum displays net optical transitions of *s*- and metallic (*m*)-SWNT over the entire absorption region. Moreover, we were able to measure the extinction spectrum of CIs, which should be of use to workers in the field. Finally, the effects of the CI on the properties of the SWNT were investigated using electrical conductivity (σ) and thermal conductivity (κ).

2. Methods

2.1. Materials and instrumentation

Two SWNT batches with different CI contents were utilized: plasma-torch-grown SWNTs termed PSWNTs (RN-220 SWCNTs,

batch# R26-036, nanotube purity of >70%, NanoIntegris, Canada) and super purified PSWNTs termed SPSWNTs (SPT-220 SWCNT, batch# PL32-059, nanotube purity of 95–99%, NanoIntegris, Canada). Their SWNT diameter (d_t) distribution is 1.3 ± 0.35 nm. SWNTs with different average d_t are high-pressure carbon monoxide (HiPco) process-generated SWNTs (d_t distribution: 1.0 ± 0.35 nm, Raw grade, batch #: HR35-067, minimum SWNT contents > 65%, NanoIntegris, Canada) and larger d_t SWNTs (LDSWNTs, d_t distribution < 3.0 nm, CAS #: 308 068-56-6, TCI, Japan). Measurements were carried out at room temperature unless otherwise noted. Gravimetric analyses of CIs and SWNT were made using a high-precision balance (0.01 mg precision, NewClassic MS, Mettler Toledo, OH, USA).

2.1.1. TEM measurements. TEM measurements were conducted using a Tecnai G² F30ST (FEI company, OR, USA) operating at an accelerating voltage of 300 kV. For TEM measurements, copper TEM grids covered with an ultrathin carbon support (LC200-Cu, lot no.: 180 912, 200 mesh, TED Pella, USA) were floated in an upside-down manner on the top of a drop of nanomaterial dispersion on a glass slide substrate. To adjust the sample concentration on the TEM grid, the sample-adsorbed grid was washed with drops of a pure dispersion solvent. After the dilution step, the grid was dried under vacuum overnight.

2.1.2. Absorption measurements. UV-vis-MWIR absorption spectra up to 3200 nm were recorded using a JASCO V-770 (Japan) using absorption cuvettes having a 1 mm path length (21/Q/1, Starna scientific, UK). Absorbances were measured *via* a double-beam configuration. UV-vis regions are dispersed by 1200 lines per mm grating and the MWIR region is dispersed by 300 lines per mm grating. D_2 and halogen lamps were used for excitation at 190 to 350 nm and 330 nm to 3200 nm, respectively. The wavelength accuracy was 0.3 nm for UV-vis and 1.5 nm for MWIR regions. The photometric accuracy is 0.0015 Abs for 0 to 0.5 Abs, and 0.0025 Abs for 0.5 to 1 Abs. Detectors for UV-vis and NIR regions were photomultiplier tubes and PbS photoconductive cells.

2.1.3. FT-IR measurements. The spectra were acquired using a Jasco FT-IR 4700 spectrophotometer in the range of 400 to 4000 cm^{-1} . The spectra were accumulated 32 times. The SWNT dispersions were introduced to a liquid sample cell (Barnes demountable liquid cell kit, beam path length: 1 mm, KBr crystal). Precaution was taken to exclude air bubbles in the cell. The spectra were stitched in the 2900–3200 nm region of the absorption spectra recorded using a UV-vis-MWIR absorption spectrometer.

2.1.4. Resonance Raman spectroscopy measurements. Raman spectra were recorded using a custom-made setup²⁸ with a 532 nm laser (Cobolt, Hübner Photonics, Germany) with 0.1 mW power and a 50 \times objective lens (MPlan, NA = 0.75) *via* a backscattering geometry and were calibrated using the Si peak (520.89 cm^{-1}) as the internal reference.

2.1.5. SEM measurements. SEM measurements were conducted using Schottky emission SEM (SU-70, Hitachi, Japan) operating at an accelerating voltage of 10 kV. SEM images of SWNT films were obtained at a working distance of *ca.* 11 mm



under the condition of 100 k magnification. All measurements were conducted without any conductive metal coating.

2.1.6. Atomic force microscope (AFM) measurements. AFM measurements were conducted using a commercially available AFM (NX10, Park systems, Republic of Korea). An Al-coated silicon cantilever with a spring constant of 37 N m^{-1} , a resonance frequency of 300 kHz, and quoted radius of *ca.* 6 nm (ACTA, App Nano, USA) was utilized to measure height topographies. Typically, a 512×512 pixel image was collected from $5 \mu\text{m} \times 5 \mu\text{m}$ area. Prior to AFM measurements, SWNTs with various d_t were deposited onto 285 nm-thick SiO_2/Si substrates by dipping into the SWNT dispersion for 30 min. Then, the substrate was rinsed several times with fresh methanol and dipped into fresh methanol to remove residual flavin completely. After that, the rinsed substrate was dried under a N_2 flow. In the case of SPSWNTs, 200 μL of dispersion was drop-casted onto a substrate. After 10 min, the substrate was rinsed several times with a fresh methanol until no green fluorescence originating from flavin derivatives was observed using a hand-held UV lamp (*i.e.*, 365 nm). The measured height topographies were analyzed using XEI 4.3.4 program (Park systems, Republic of Korea).

2.1.7. X-ray photoelectron spectroscopy (XPS). XPS spectra were recorded using a Nexsa XPS System (Thermo Fisher Scientific, USA). The spot size of irradiation is *ca.* 400 μm and the binding energy position was calibrated by C_{1s} position as 284.8 eV.

2.1.8. Thermogravimetric analysis (TGA). TGA measurements were conducted using a TGA Q500 (TA Instruments, USA). For this purpose, *ca.* 3 mg of nano carbon film or powder was used. Sample heating was ranged from room temperature to 900 $^\circ\text{C}$ at a ramping rate of $10 \text{ }^\circ\text{C min}^{-1}$ under a 100 standard cubic centimeter per minute flow of synthetic air composed of 21 vol% O_2 and 78% of N_2 .

2.2. Construction of Kataura plot

Since the surfactant-based SWNT dispersions were utilized, the Kataura plot was constructed based on the empirical equation of optical transitions from sodium dodecyl sulfate (SDS)-dispersed SWNTs for *s*-SWNTs²⁹ and Rayleigh scattering for *m*-SWNTs.³⁰ For *s*-SWNTs, SDS-SWNTs were adopted to have the closest match with the flavin surfactant system.³¹ On the contrary, optical transitions of *m*-SWNTs were obtained from the suspended tube in a trench since excitonic effects on *m*-SWNT³² are negligible as compared to *s*-SWNTs.³³

2.3. CI-enriched dispersions

The as-purchased PSWNTs (1 mg) were added to 4 mL of chloroform, which was dried over 3 Å molecular sieve (Alfa Aesar, MA, USA) overnight prior to use. The resulting mixture was subjected to brief bath sonication (20 min, Branson 1510, 70 W, Emerson, USA) and centrifugation at 10 kg for 10 min using a high-performance centrifuge with a fixed angle rotor (Avanti J-26 XPI and JA-25.50, respectively, Beckman Coulter, IN, USA) at room temperature using an organic solvent-tolerant centrifugal tube (50 mL, Cat. #: 3114-0050, fluorinated poly(ethylene)-co-

poly(propylene), Nalgene, USA). After centrifugation, the 70% supernatant was collected for use in further measurements. Repetitive CI extractions were conducted in a similar way. The extraction of CIs from the HiPco and LDSWNTs requires more vigorous sonication owing to the tightly adsorbed CI on SWNTs. Then, 1 mg of as-purchased SWNTs were added to 1 mL of chloroform (instead of 4 mL for PSWNTs). After brief bath sonication for 20 min, the resulting mixture was subjected to 5 h tip sonication (40% power, 25 W mL^{-1} , probe tip diameter: 13 mm, VCX 750, Sonics & Materials, USA) with a bath temperature of 15 $^\circ\text{C}$ maintained by an external water circulator (Lab Companion RW-2025G, Jeio Tech, Republic of Korea). Then, centrifugation at 10 kg for 30 min was conducted and 70% supernatant was collected. Prior to AFM measurements, the CI was deposited on SiO_2/Si substrates by dipping into the CI-enriched chloroform dispersion for 30 min. Then, the substrate was rinsed with fresh chloroform and dried under a N_2 flow.

2.4. SWNT dispersions

A mixture of 1 mg of PSWNT and 1 mg of FC12 was added to 4 mL of *p*-xylene, which was dried over a 3 Å molecular sieve overnight prior to use. The resulting mixture was subjected to brief bath sonication for mixing, and then to 1 h tip sonication (18.8 W mL^{-1}). Centrifugations at 5 kg were conducted for 2 h and the 80% supernatant was collected for use in further measurements. Sonication and centrifugation were conducted with the aforementioned equipment for CI extraction. Surfactant-free SWNT dispersion was prepared by addition of 1 mg of as-prepared PSWNTs to 4 mL of *N*-methyl pyrrolidone (NMP) with brief bath sonication (1 h). The as-sonicated NMP dispersion was used directly for TEM sampling without any centrifugation. SWNT dispersions with different d_t , CI-removed PSWNT dispersions, and SPSWNT dispersions were obtained by using FC12 with a similar protocol. An *m*-enriched FC12-PSWNT dispersion was prepared by re-dispersion of the precipitate according to our previous work.⁵

2.5. SWNT film preparation

An acetone-dissolvable membrane filter was used to prepare PSWNT films on a quartz substrate. A 0.1 μm pore-size mixed cellulose ester membrane filter (1" in diameter, cat. #: A010A025A, Advantec, Japan) was used to filter *ca.* 3 mL of PSWNT dispersion for further use. To prepare the SWNT film, the membrane filter was placed in upside-down manner on a quartz substrate (2.5 cm \times 2.5 cm \times 1 mm, NC-200, Hanjin Quartz, Republic of Korea) having 20 μL of deionized water droplet to promote better adhesion. A dummy top slide glass was placed and pressurized on the top of the membrane filter/SWNT film for few seconds to promote even adherence of the membrane filter on SWNTs. After the dummy slide glass was removed, the entrapped DI water was carefully removed using a tissue wiper along the perimeter of the membrane filter, and the membrane-adhered quartz substrate was quickly loaded into a custom-made acetone vapor reflux chamber prior to dryness. Special care was taken in placing the quartz substrate,



so it does not come in direct contact with the acetone drop condensed by a reflux condenser. The dissolution of the membrane filter can be observed by melting out a whitish membrane residue within few hours and the complete removal time required is two days. The average thickness of each PSWNT film was measured more than five times using a surface profiler (Dektak XT, Bruker, USA) for σ and κ analyses.

2.6. Deterministic transfer of SWNT films to a prepatterned device

The PSWNT film transfer process was adopted from a poly(methyl methacrylate) (PMMA)-assisted graphene transfer method.^{28,34} Deterministic transfer of thin SWNT films follows the previous protocol.³⁵ In order to transfer the SWNT film on a quartz substrate to a prepatterned chip, a PSWNT film-placed quartz substrate was initially spin-coated with PMMA (molecular weight: 950 kDa, 2% dilution in anisole (A2), MicroChem, MA, USA) at 1000 rpm for 60 s (SF-1A, BGK, Republic of Korea). After that, a PMMA-coated PSWNT film was cut carefully using a sharp blade to make the rectangular film (5 mm \times 3 mm size), which fits on the desired area of the pre-patterned chip. The PMMA-coated PSWNT film was carefully detached from a quartz substrate by floating on a buffered oxide etchant (10 : 1 volume ratio, 36% of NH_4F and 4.7% of HF , etching rate: 1 nm s^{-1} at 25 $^\circ\text{C}$, Sigma-Aldrich, MO, USA) for 2 h. The floated PSWNT film with the PMMA coating was scooped out using a clean slide glass and washed with the residual oxide etchant and subsequently with DI water two times. The rectangular PSWNT film

was transferred to an exact position of a pre-patterned chip (lithographically defined Pt electrodes (100 nm) on a 300 μm -thick (100) Si substrate with a suspended Si_3N_4 layer (100 nm) and an Al_2O_3 passivation layer (30 nm))³⁶ via a custom-made x - y - z transfer system described in our previous report.³⁵ To remove the PMMA coating on the PSWNT film, the chip was immersed in a clean acetone bath overnight and dried at 90 $^\circ\text{C}$ under 10^{-3} torr vacuum.

2.7. σ and κ measurements

Both σ and κ measurements were conducted using a thin film analyzer (TFA, Linseis, Germany) based on a previous report.³⁶ σ was measured by the 4-point van der Pauw method using the determined thickness. κ was obtained by the 3ω method to correct for the thermal conductivities of the 100 nm-thick Si_3N_4 layer and the Al_2O_3 passivation layer. All measurements were conducted under high vacuum up to 7.5×10^{-6} torr.

3. Results and discussion

In the first phase of this investigation, the morphologies of the components of as-purchased PSWNTs were explored. The quoted contents of the PSWNT are 85–90% SWNTs and CIs, and 10–15% of a trace metal catalyst.¹⁷ The morphology of this material, dispersed in NMP using 1 h bath sonication, was investigated by TEM. The TEM image in Fig. 1A shows that the sample comprises bundled SWNTs and nearby CI particles, suggesting that a strong interaction exists between equal

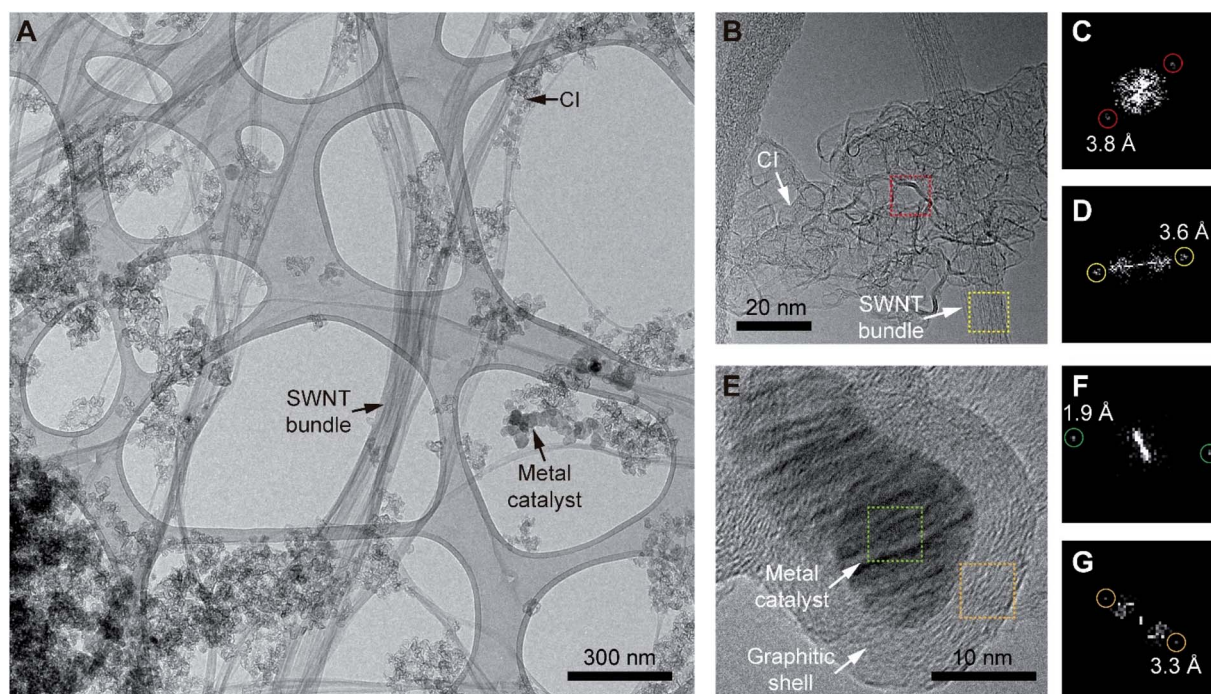


Fig. 1 Morphologies of components in the as-purchased PSWNT, which were obtained by TEM on a sample prepared using a sonication-assisted NMP dispersion. TEM images of (A) SWNT, CI, and metal catalyst, (B) CI agglomerates near the SWNT bundle and (E) metal catalysts covered by graphitic shells. FFT images of (C) CI and (D) bundled SWNT regions obtained from boxes in (B). FFT images of (F) metal catalyst and (G) graphitic shell regions obtained from boxes in (E).



graphitic sidewalls of the two components. The magnified view in Fig. 1B shows that the CI exists in a disk-like agglomerated form with edge-scrolled, crumpled flakes with a size of 10–20 nm. Moreover, fast Fourier transform (FFT) image of the scrolled area (Fig. 1C) shows the presence of a few-layered graphene structure with a layer spacing of 0.38 nm. This result indicates that the CI has a defect containing few-layered graphene structures, which contrasts with that of highly crystalline graphite that has a vdW distance of 0.34 nm and bundled PSWNT that has 0.36 nm spacing between the tubes (see FFT image of Fig. 1D). In addition, the morphology of the CI is different from that of CB, which has an onion-like graphitic shell structure and a large number of sp^3 carbons.³⁷

As compared to the CI whose inner part is empty, the metal catalyst comprised of Ni, Fe, and Co^{17,38–40} (Fig. 1E) has a comparable size and is present as a filled sphere. In addition, the metal catalyst has a comparable size to that of the CI and is covered by a graphitic shell. The FFT images of the catalyst (Fig. 1F) and shell part (Fig. 1G) contain diffraction spots with sizes of *ca.* 0.19 nm and 0.33 nm originating from the (200) reflection of metallic Ni (ref. 41) and the (002) reflection of graphite, respectively. A consideration of the sizes and the graphitic layers commonly observed in the CI and the metal catalyst suggests that the CI originates from graphitic carbon formed during the growth of the SWNT. Overall, the CI in PSWNT is an edge-scrolled defect containing few-layer graphene agglomerates nearby PSWNTs.

As CI contributes to a background signal in the absorption spectrum of SWNT batches, understanding its absorption feature is important. As part of a study aimed at generating

purier forms of SWNTs, we found that chloroform serves as a solvent to selectively disperse CIs from PSWNTs. The dispersion is prepared by 20 min sonication of a mixture of PSWNTs (1 mg) and dry chloroform (4 mL) followed by 10 kg centrifugation for 10 min. A photograph displayed in the inset of Fig. 2A shows that the generated dispersion has a pitch-black color. The corresponding UV-vis-MWIR absorption spectrum of CI (Fig. 2A) in the dispersion comprises a featureless curve in the 200–3200 nm range along with a π plasmon band at 261 nm, which originates from the graphitic carbon structure.^{42,43} Moreover, the measurement of the FT-IR spectrum and stitching to Fig. 1A (Fig. S1 of ESI†) yields the featureless absorption spectrum up to 8000 nm. Clearly, 5847, 6233, and 7337 nm bands are corresponding to the carbonyl bands (*i.e.*, 1710, 1604, and 1362 cm^{-1}), phenol, *etc.* (see ESI† for detailed FT-IR assignment), respectively. This result indicates that defects of CI mainly originate from the oxygenated defects.^{44–46} The remaining IR features are associated with chloroform. Interestingly, the MWIR spectral region resembles that of graphenes^{47,48} rather than that of CB (ref. 49) (see Fig. S2A, S2B, and S2C† for absorption comparison of CI, CB, and graphenes). The concave and converse absorption features of respective CI and CB made a clear distinction. The smooth region in the spectrum of the CI-containing dispersion up to 8000 nm was best-fitted (*i.e.*, $R^2 = 0.99925$, Fig. S1†) using a biexponential curve (red):

$$y = A_1 e^{-\frac{x}{b_1}} + A_2 e^{-\frac{x}{b_2}} + y_0 \quad (1)$$

where A_1 and A_2 are the coefficients of each exponential, b_1 and b_2 are the fitting parameters, and y_0 is a constant. The values

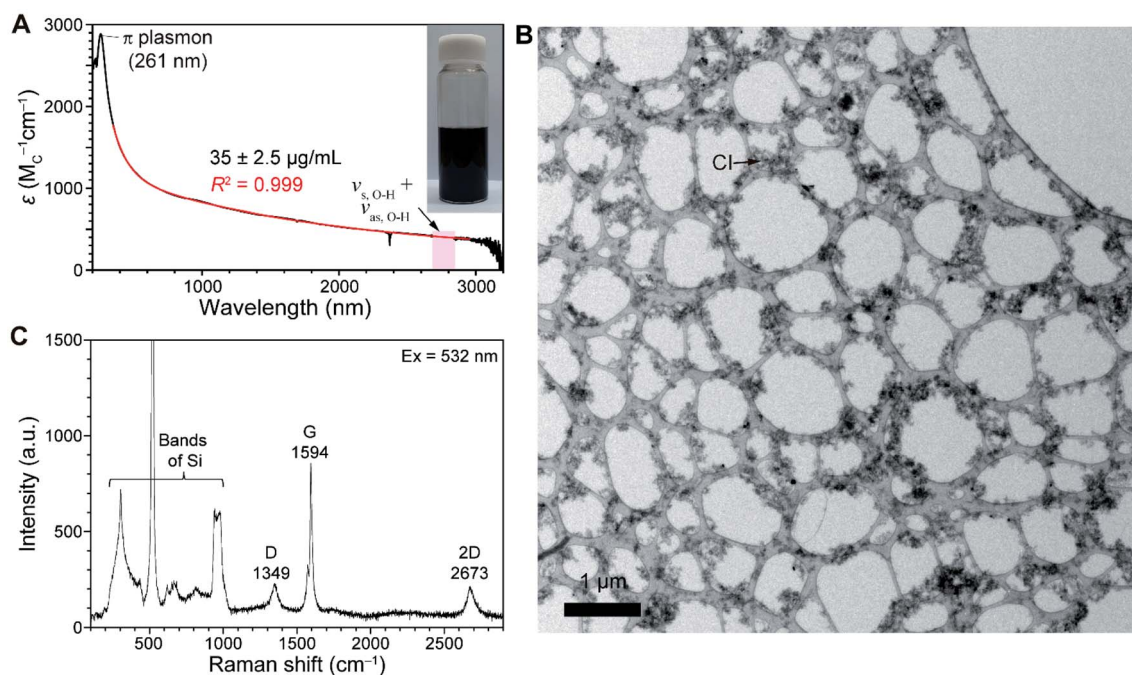


Fig. 2 CI-containing chloroform dispersion of the as-purchased PSWNTs. (A) UV-vis-MWIR absorption spectrum (black) and its biexponential fitting curve (red) of the chloroform dispersion. Shaded area denotes symmetric and asymmetric vibrations of O–H appearing at 2900 nm. Inset: a photograph of the dispersion in chloroform. (B) The corresponding representative TEM image of the dispersion, showing CI agglomerates as major constituents. (C) Raman spectrum of CI deposited on a 285 nm-thick SiO_2/Si substrate. Raman bands below 1000 cm^{-1} originated from Si.



determined for A_1 , A_2 , b_1 , b_2 and y_0 are 1174, 15 055, 1641.9, 110.5, and 186, respectively. These observations along with those arising from TEM studies confirm that the chloroform dispersion consists mainly of CIs. The inspection of TEM images of materials in the chloroform dispersion (Fig. 2B and S3A†) shows that the vast majority of the dispersion comprises CI agglomerates, along with trace amounts of the metal catalyst. The magnified views in additional SEM images of the thick film (Fig. S3D†) supported that selective CI dispersion in chloroform contains massive CIs with few SWNTs.

Studies were carried out to generate exact weight samples of the CI required for determining extinction coefficients (ϵ) in the absorption spectrum. We found that dry CIs can be obtained by filtration of the CI dispersion arising from sonication of 1 mg as-purchased SWNTs in 4 mL chloroform with a filter membrane followed by drying. The dried sample removed from the filter membrane weighing $35 \pm 2.5 \mu\text{g mL}^{-1}$ has a brittle and cracked film morphology due to its globular particle structure. Using this sample to generate an absorption spectrum (Fig. 2A), we were able to obtain ϵ of CI at different wavelengths (e.g., $1170 (\text{carbon } M \text{ or } M_C)^{-1} \text{ cm}^{-1}$ at 550 nm). Comparison of absorption cross section (σ_{abs}) with monolayer graphenes provides more insights into the nature of CI. Specifically, σ_{abs} of the CI, determined using the formula $\sigma_{\text{abs}} = 2.3\epsilon/N_A$, where N_A is Avogadro's number ($6.02 \times 10^{23} \text{ mol}^{-1}$), is $4.47 \times 10^{-18} \text{ cm}^2 \text{ C}^{-1}$ (see ESI† for the detailed calculation). This value is about 76% of the one ($5.9 \times 10^{-18} \text{ cm}^2$) based on 97.7% transmittance of monolayer graphenes.⁵⁰ This result indicates that the CI consists of a defective graphene structure.

The Raman spectrum of isolated CI, deposited on a 285 nm-thick SiO_2/Si substrate, was obtained (Fig. 2C). Along with Raman bands originating from Si below 1000 cm^{-1} ,⁵¹ the spectrum produced by excitation at 532 nm exhibits two prominent bands near 1350 cm^{-1} and 1594 cm^{-1} originating from disordered D and graphitic G bands that are commonly observed in graphitic nanocarbon.^{52,53} In addition, G band intensities are much stronger than that of the 2D band, suggesting graphitic structures. Moreover, the significant D band intensity indicates a defective graphene structure. However, the spectrum is quite different from those observed for amorphous carbon and CB, which contain larger D bands than G bands, and a concomitant D' band near 1620 cm^{-1} .⁵³ Based on the intensity ratio of D over G bands (I_D/I_G) of the CI (i.e., 0.267) and CB (i.e., 0.87), the defect density L_D was calculated as 23 and 12 nm, respectively (see ESI† for defect density calculations). This result indicates that the CI has a greater crystalline portion than CB, leading to large contributions in the absorption spectrum.

A plot of optical transitions vs. d_t of the SWNT (Kataura plot^{29,30,54} in Fig. 3A) can be employed for determining the reference point to understand the contribution of CIs from the SWNT spectrum. *s*- and *m*-symbols up to 3 nm d_t were obtained from the respective SDS-encapsulated *s*-SWNT dispersion²⁹ and Rayleigh measurement of suspended *m*-SWNTs³⁰ respectively to consider the excitonic effect of SWNTs (see Methods). Therefore, SWNTs with the largest d_t existing for a given batch was utilized to set the lower bound of optical transition-devoid wavelength region situated above the resulting lowest lying

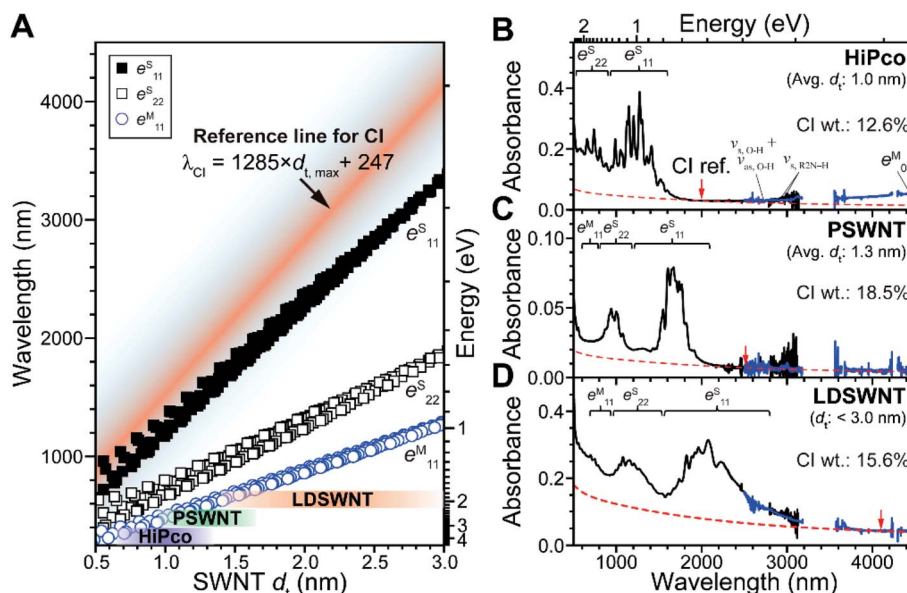


Fig. 3 Quantification of CIs present in SWNT batches with different d_t ranges. (A) Kataura plot of d_t vs. optical transition wavelengths based on SDS-wrapped *s*-SWNTs (square) and Rayleigh scattering-based *m*-SWNTs (circle), as reported in the literature.^{29,30} Purple, green, and brown areas denote d_t ranges of each SWNT species. The separation of absorption spectra into SWNT and CI contributions with SWNT batches using the wavelength region containing the least optical transitions corresponding to SWNTs. The absorption spectra of (B) HiPco, (C) PSWNT, and (D) LDSWNT dispersed by FC12 and *p*-xylene in a similar manner. Background absorption of CI is denoted as a dashed curve. Reference points of CI for each SWNT batch were indicated by red arrow. CI reference points of B, C, and D are 1982, 2496, and 4102 nm, respectively, based on eqn (2).



optical transition owing to the inverse relationship between d_t and optical transitions in energy. This is accomplished by setting a reference point (red line in Fig. 3A) that is distinct from optical transitions of SWNTs with different d_t , considering full width at half maximum of optical transitions of SWNTs (*i.e.*, 20–30 meV for the first optical transitions (e_{11}^S) of *s*-SWNTs⁵⁵) and slight SWNT bundling (*i.e.*, 20–56 meV for the optical transitions for SWNT bundles⁵⁶). Shaded color-coded areas in the plot correspond to SWNT species with different d_t distributions, in which the quantification of CI is examined. The species, including HiPco process SWNT (d_t distribution: 1.0 ± 0.35 nm), PSWNT (d_t distribution: 1.3 ± 0.35 nm), and LDSWNT ($d_t < 3.0$ nm), were dispersed by sonochemistry using isomolar FC12 (*i.e.*, 0.61 mM) in *p*-xylene and a protocol described in the Methods section. In the Kataura plot, each SWNT with known d_t distribution has an e_{11}^S optical transition-devoid wavelength region (red line and above) in the MWIR region, which is used as the CI reference point to determine the net contributions of the SWNT and CI.

The combined results led to empirical derivation of an equation for finding the reference point used for CIs in nm (λ_{CI}) in correcting various SWNT spectra. The relationship considering the aforementioned full width at half maximum of SWNTs and slight SWNT bundling is as follows:

$$\lambda_{CI} = \alpha d_{t, \max} + \beta \quad (2)$$

where α and β denote coefficients, and $d_{t, \max}$ represents the maximum diameter of a given SWNT. The dimensionless coefficient α is 1285 and β is 247 nm. Using this equation, one can estimate λ_{CI} for a SWNT having known d_t ranges. The biexponential fitting curve in eqn (1) was utilized to subtract those reference points.

We explored several examples in which this protocol was employed to determine the net spectral contributions of the SWNT and CI. It was reported that a FC12-SWNT dispersion created using aromatic solvents such as *p*-xylene and toluene is enriched in individualized *s*-SWNTs and CIs, and does not contain large amounts of bundled SWNTs.^{5,31,55} This fact assures that background absorption in the absorption spectra of the SWNT dispersion mostly originates from CI. The absorption spectrum of the IR region (2500 to 25 000 nm, blue) from FT-IR measurement was stitched in the 2900–3200 nm region of the absorption spectrum acquired using a UV-vis-MWIR absorption spectrometer (black). In the FT-IR region, vibrations originating from surfactants, residual water, and *p*-xylene were also observed (see ESI† for the vibration assignments). At first, bands in the spectra of a PSWNT dispersion (Fig. 3C), whose e_{11}^S tails up to 2100 nm, are expected not to have *s*-SWNT contributions in the region higher than 2100 nm. Moreover, the e_{00}^M band, originating from an opened band gap in the density of state continuum caused by SWNT curvature and doping,^{57,58} typically occurs in the MWIR region (3000 to 25 000 nm) for *m*-SWNTs with small d_t . For PSWNTs with a d_t distribution of 1.3 ± 0.35 nm, 2496 nm was obtained using eqn (2). The resulting subtracted spectrum (Fig. S4†) has nearly no absorbance from 2300 nm.

In a similar manner, contributions of CIs to the spectra of HiPco (Fig. 3B) and LDSWNT (Fig. 3D) dispersions were determined by adjusting the CI spectrum to the reference point in the Kataura plot. HiPco with the smallest d_t among three SWNT samples was set to have a reference position at 1982 nm and LDSWNTs with the largest d_t at 4102 nm which is the IR region. Upon closer look, the MWIR region (*i.e.*, 3000–4500 nm) of the HiPco sample displays rising absorption above the CI absorption (red dashed line). This originates from the e_{00}^M band of *m*-SWNT. Investigation up to long-wavelength and far IR region (8000 to 25 000 nm, Fig. S5†) shows that HiPco and LDSWNT samples exhibit e_{00}^M while PSWNT does not have. Moreover, HiPco shows maximum of e_{00}^M at *ca.* 10 000 nm (1000 cm^{-1}) while LDSWNT exhibits rising absorption up to 25 000 nm (400 cm^{-1}). This clearly indicates that those absorptions depend on the d_t range of the *m*-SWNT in each sample. This is in line with *m*-SWNT observation using the IR region.^{59,60}

By using both of these approaches and the determined ϵ value of CI, we deduced the SWNT concentrations present in various SWNT dispersions. For this, we obtained overall weights in each SWNT dispersion with known absorbance. Separately, the CI concentration was obtained by ϵ using CI reference points for each sample (CI concentration: $7.19 \pm 0.52 \mu\text{g mL}^{-1}$ in HiPco dispersion, $1.93 \pm 0.14 \mu\text{g mL}^{-1}$ in PSWNT dispersion, and $15.6 \pm 1.1 \mu\text{g mL}^{-1}$ in LDSWNT dispersion). The filtration of each dispersion using a 1.0 μm pore-sized PTFE filter followed by complete acetone washing results in the production of films containing both SWNTs and CIs (HiPco: $49.8 \pm 0.62 \mu\text{g mL}^{-1}$; PSWNT: $8.53 \pm 0.15 \mu\text{g mL}^{-1}$; LDSWNT: $84.1 \pm 1.2 \mu\text{g mL}^{-1}$). It is noteworthy that the filtrate did not contain either PSWNTs or CIs. This result indicates that although the absorption spectrum appears to indicate that a small amount of CI is present, it exists in the significantly large weight of 12.6, 18.5, and 15.6% in HiPco, PSWNTs, and LDSWNTs, respectively. Among various SWNT dispersions, HiPco has the smallest CI content, whereas the PSWNT has the largest. The observed increasing CI contributions with the increase in average d_t in the absorption spectra (Fig. 3B to D) might appear contrasting with the quantified CI weight percentage. However, consideration of both significant *m*-SWNT contents in LDSWNTs and near-absent *m*-SWNT contents in PSWNT explains such CI weight difference.

CI content trends of these SWNTs were confirmed by both SEM and AFM. First, to determine how the morphologies of CI are different for given SWNT batches, SWNT films from each dispersion were prepared by a filtration method. The SEM images (Fig. 4A to C) regardless of the samples display that CIs are much brighter than overall SWNTs. As the *m*-SWNT has much brightness than that of the *s*-SWNT under the SEM image due to higher secondary electrons originating from free electrons,⁶¹ so does metallic CI. Based on this, CI is marked in red, as shown in Fig. 4A' to 4C'. Clearly, CIs in HiPco and LDSWNTs were much conformally bound to the SWNT surface and have a much smaller size (few nm) than that of the PSWNT. Moreover, CIs of the PSWNT are more clustered and much higher contents. This is in line with the determined CI contents in each SWNT batch and the reason why the CI in PSWNT can be



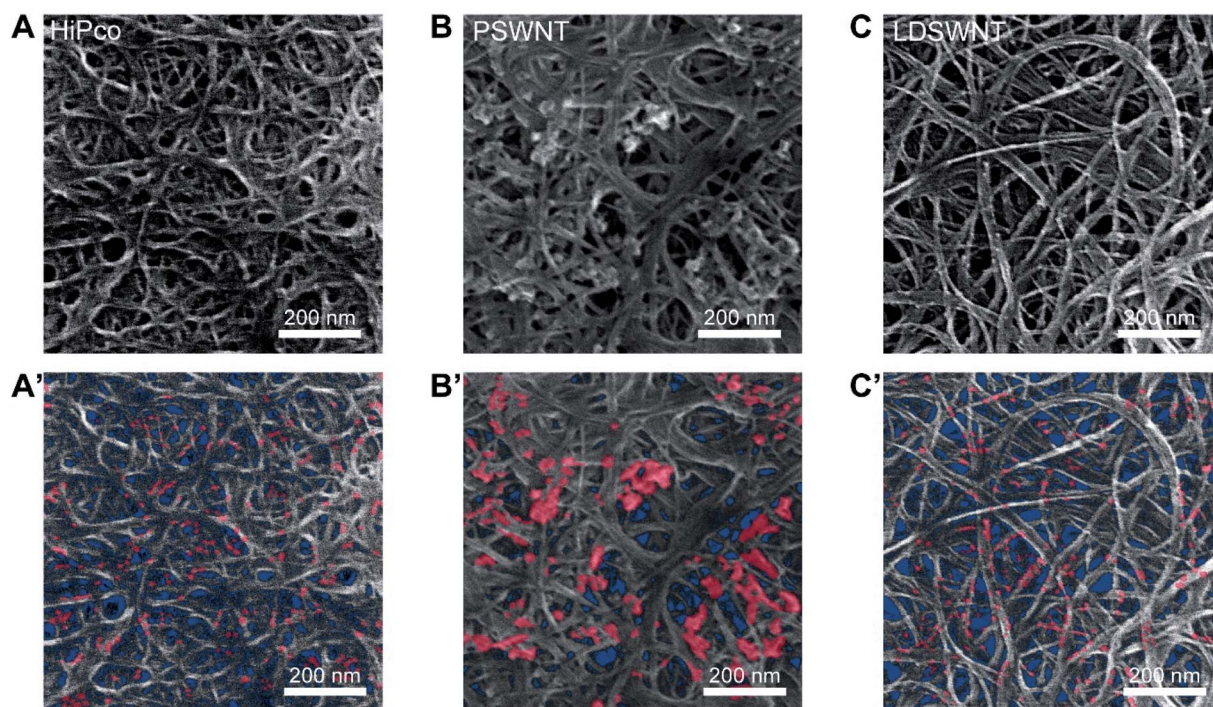


Fig. 4 Visualization in the morphologies of the CI present in each SWNT film. (A to C) SEM images and (A' to C') CI-marked (red) SEM image of each film. The background in the SEM images was colored in blue for visual clarity.

relatively easily removed by chloroform extraction. The AFM results also unequivocally support such proposition. Fig. S6A to S6C† show the AFM height images of the respective SWNT deposited on a 285 nm-thick SiO₂/Si substrate after extensive washing with acetone to remove any residual FC12. Although repetitive washing with acetone, while the PSWNT sample (Fig. S6B†) exhibits a smooth individualized SWNT surface and CI according to the previous literature,³¹ HiPco (Fig. S6A†) shows an irregular height topography on SWNTs along with LDSWNTs to a lesser extent (Fig. S6C†), suggesting adsorbed CI. Each growth method of SWNT results in different CI morphologies.

To determine whether chloroform-based CI extraction method can be utilized for the removal of the conformally bound CIs on SWNTs, similar CI extractions for HiPco and LDSWNT samples were conducted. The exfoliation of CIs on those SWNT surfaces requires more vigorous tip sonication with extended time as compared to bath sonication for PSWNTs. The absorption spectra of the resulting CI-enriched dispersion (Fig. S7A and S7B†) resemble the biexponential curve of CI of eqn (1) (red), except the overtone (1694 nm) and combination (2371 nm) of chloroform vibrational features.^{62,63} The AFM measurement of each extracted CI (inset of Fig. S7A and S7B†) shows globular CI morphologies, which are ascribed to the spontaneous graphene scroll in dissimilar solvents.^{64,65} This experiment indicates that the CI morphology determines the degree of CI extraction using chloroform.

To confirm the weight percentage measurements, we prepared a bulk sample for TGA. Prior to carrying out this analysis, a FC12-PSWNT dispersion was filtered and washed

with copious amounts of acetone. The result of XPS (Fig. S8A to S8C†) confirmed that PSWNTs, acetone-washed PSWNTs and CI samples do not contain appreciable nitrogen contents (*i.e.*, below 0.5%, respectively, Fig. S8D†), suggesting that no appreciable flavin surfactant is present in the film. In addition, the increased oxygen content (*i.e.*, 2.0 to 6.2%) at the expense of carbon content (97.5 to 93.3%) for PSWNT/acetone-washed PSWNTs is due to the oxidation of SWNTs and nanocarbons during sonication, whereas the CI displays similar atomic contents with PSWNTs. It is noteworthy that *ca.* 2% of oxygen present in the CI mainly originates from the carbonyl functionality observed in the FT-IR measurement. The results of TGA (Fig. S9A to S9C†) show that PSWNTs, CIs, and acetone-washed PSWNTs have different thermograms against air. For instance, while the CI displays a lower decomposition temperature (a maximum weight loss at 600 °C), acetone-washed PSWNTs display a higher decomposition temperature by 40–80 °C (a large weight loss at 640–680 °C). The TGA trace of PSWNTs is in between that of CIs and acetone-washed PSWNTs. Fitting the thermogram from PSWNTs shows that respective contributions from CI and PSWNT of *ca.* 20% and 80% (Fig. S9D†) give the closest match with the above-determined weight percentage of CIs in PSWNTs (*i.e.*, 18.5%).

We demonstrated the efficacy of using chloroform to separate CIs from PSWNTs by comparing the produced PSWNT to the as-purchased PSWNT, which compared to PSWNTs has a 1–3% CI content. For this purpose, the CI was repetitively extracted from PSWNTs using chloroform (see Methods). Fig. 5A to D display the normalized UV-vis-MWIR spectra of FC12-PSWNT dispersions obtained from varying extraction



times (*i.e.*, without extraction, 3 times, and 6 times). While the spectra are not greatly different in terms of intensities of optical transitions and *m/s*-ratios of PSWNTs, it is clear that the CI contribution is lowered by increasing the number of extractions (see dashed lines in Fig. 5A to C). In addition, the chloroform extraction with 6 times results in reduced overall weight by 78% and increased SWNT purity (81 to 91%), as shown in Fig. S10.† Overlaid CI-subtracted net SWNT spectra with varying number of extraction (Fig. S11†) indicate that the spectra remain similar, suggesting a negligible change in PSWNT distribution along with the effective removal of CI. Especially, 3 to 6 times extracted samples have a lower CI level as compared to SPSWNTs, as shown in Fig. 5D. Moreover, comparison of PSWNTs without chloroform extraction and SPSWNTs indicates that there are significant e_{11}^s and higher transition shifts to a longer wavelength, possibly due to the oxidative instability of the smaller- d_t PSWNT during the CI removal step for SPSWNT preparation. Moreover, SPSWNTs prepared under mild oxidation conditions are about 40 times expensive as compared to PSWNTs.³⁰

Those trends were confirmed by AFM height measurements. The corresponding AFM images after acetone treatment (Fig. 5E to G) show that the CI content decreased remarkably after 3 times CI extraction. In addition, as the CI extraction proceeded up to 6 times from as-purchased SWNTs, the average number of CIs per SWNT length (Fig. S12†) continued to decrease (*i.e.*, 2.17 ± 0.34 , 0.69 ± 0.32 and 0.32 ± 0.05 CI/SWNT length (μm) for without extraction, 3 times extracted and 6 times extracted

samples, respectively). This value of the 6 times extracted sample is comparable with that of the SPSWNT sample (0.21 CIs per $1 \mu\text{m}$ SWNTs) (Fig. 5H). Comparison between the use of the chloroform extraction and oxidative CI removal methods clearly demonstrates that the former method is facile and it does not greatly disturb the original SWNT distribution.

The effects of CI on σ and κ , two important physical properties of a SWNT, were elucidated. The device used for this purpose contains both pre-patterned σ and κ measuring components (see Fig. S13† for the detailed configuration), enabling simultaneous measurements of thin SWNT films to be made. PSWNT films of varying CI contents were transferred onto an electrode-pre-patterned substrate, as shown in Fig. 6A and S14† (see Methods). A deterministic transfer method was utilized to transfer the thin SWNT film (Fig. 6A), according to the literature.³⁵ This method consists of the following steps: (i) filtration of SWNT dispersion on a membrane, (ii) transfer of SWNT films to a quartz substrate by dissolution of the membrane, (iii) PMMA spin-coating onto a SWNT film/quartz substrate, (iv) floating PMMA/SWNT films from the quartz substrate by buffered oxide etchants, and (v) transferring onto a desired substrate using two sets of translators and dissolution of the PMMA layer with acetone. Prior to step (iv), the film is cut into a desired size ($5 \text{ mm} \times 3 \text{ mm}$).

PSWNT dispersions containing different amounts of CI were prepared to determine the effect of weight percentage of CI on σ and κ . FC12-PSWNT dispersions with specific CI weight percentage (*i.e.*, 1.93, 3.86, 9.65, 19.3, and $38.6 \mu\text{g mL}^{-1}$ or 18.5,

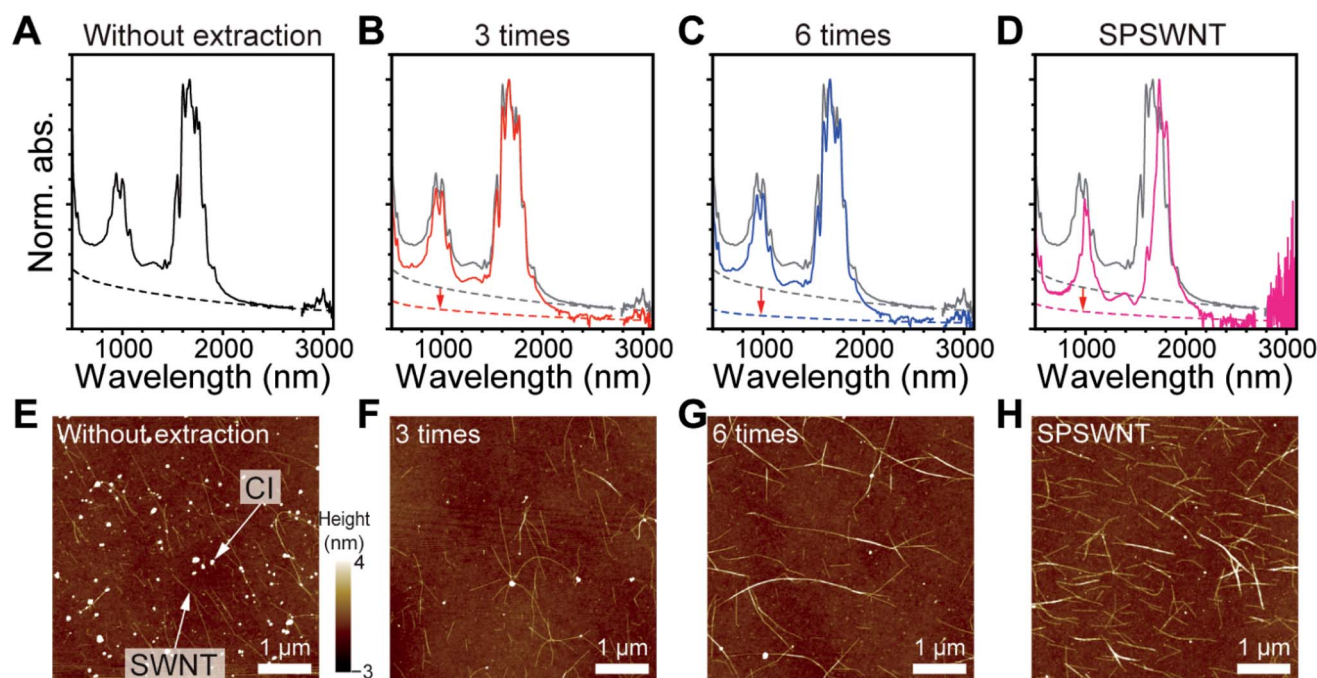


Fig. 5 Effects of repetitive chloroform extraction of PSWNTs on SWNT distribution and degree of CI removal. UV-vis-MWIR absorption spectra from (A) without chloroform extraction (black), (B) 3 times chloroform extraction (red), (C) 6 times chloroform extraction (blue) samples, and (D) SPSWNT dispersion (magenta), which were dispersed by FC12 in *p*-xylene. Dashed lines indicate CI contributions to the spectra. Grey spectra were originating from the sample without chloroform extraction for visual comparison. (E–H) The corresponding AFM height images whose samples were deposited on 285 nm-thick SiO_2/Si substrates. FC12 was completely washed with acetone.



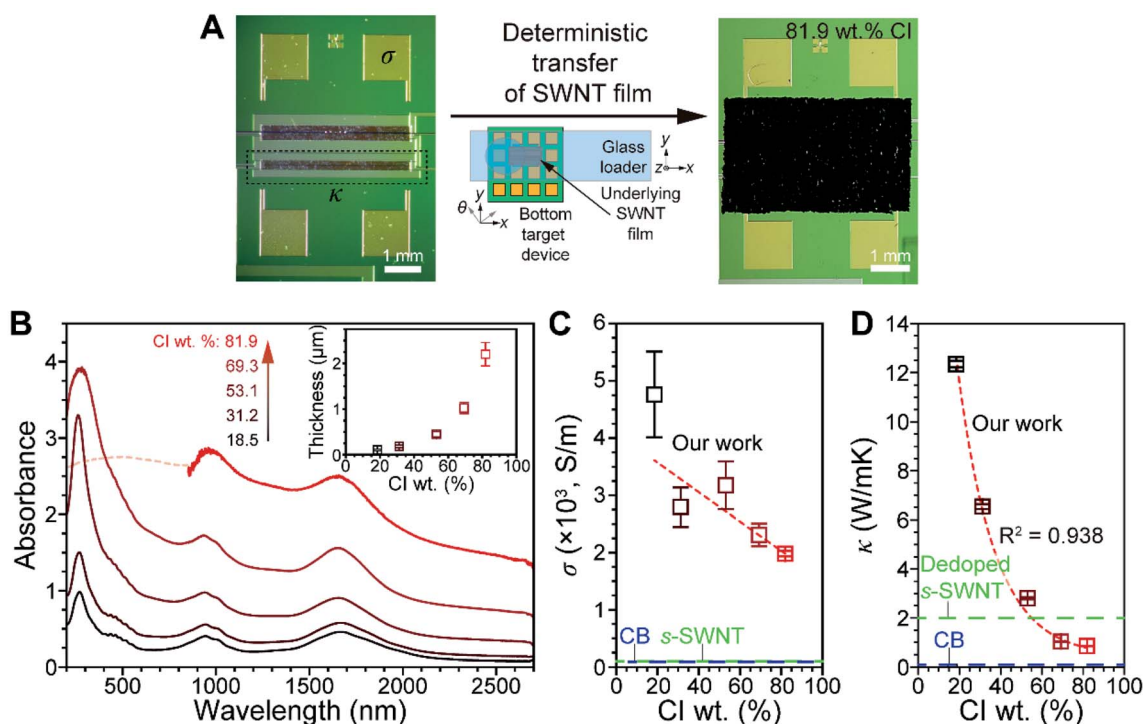


Fig. 6 Effect of CI contents on the physical properties of a PSWNT film. (A) Schematic of the deterministic transfer of PSWNT films with the largest CI content. Left and right photographs are before and after the transfer of the PSWNT film. Four Au electrodes were utilized for the σ measurement and the dashed box area is used for the κ measurement. (B) Absorption spectra of PSWNT films with the increase in CI concentration on quartz. Inset: thickness change of PSWNT films measured using a surface profiler. The error bars for thickness were obtained by averaging the thicknesses of five different areas. Plots of (C) σ and (D) κ vs. CI weight percentage in PSWNT films, and comparison with CB and s-SWNTs.

31.2, 53.1, 69.3, and 81.9 wt% in carbon) were prepared by adding the CI-enriched powder to FC12-PSWNT dispersions. Upon increasing the CI weight percentage in the PSWNT dispersion, background absorption originating from the CI increases proportionally without changing the optical features of PSWNT (Fig. S15†). The dispersions were subjected to filtration and films were prepared by dissolution of the filtration membrane using acetone vapor to remove FC12 (see Methods). After step (ii) (Fig. 6B), the absorption spectra of the produced PSWNT films were acquired. The spectra contain broad and featureless e_{11}^M , e_{22}^S , and e_{11}^S bands owing to PSWNT bundling. Separately, the average thickness of each PSWNT film was varied from 104 to 2201 nm with the films having increasing roughness (Fig. S16A to S16E† for each height profile).

The σ and κ values of PSWNT films containing varying CI weight percentages (Fig. 6C and D) were obtained under vacuum conditions (*i.e.*, 7.5×10^{-6} torr). Plots of σ and κ vs. CI weight percentage show that both values decrease with the increase in CI weight percentage. For instance, σ values decrease from 4800 to 2000 $S m^{-1}$ as the CI weight percentage increases. These values lie in between those of purified *m*-SWNT (*i.e.*, $5 \times 10^4 S m^{-1}$) and *s*-SWNT (*i.e.*, 100 $S m^{-1}$) films,⁶⁶ and are much greater than that of CB (*i.e.*, 90 $S m^{-1}$).⁶⁷ It is reasonable that the sample with the highest CI weight percentage shows greater σ than that of CB since CI has less defects. In addition, κ values decrease from 12 to 0.8 $W mK^{-1}$ with the increase in CI

weight percentage, and they are much smaller than κ of *m*-SWNT (100 $W mK^{-1}$) and *s*-SWNT (200 $W mK^{-1}$) films.⁶⁸ Interestingly, κ undergoes a greater change than does σ with the increase in CI weight percentage.

Empirically, the Wiedemann–Franz law⁶⁹ suggests that the ratio of κ to σ of a metal is proportional to the temperature according to $\kappa/\sigma = LT$, where L is the Lorenz number ($2.44 \times 10^{-8} W\Omega K^{-2}$). In our case, samples with 18.5–81.9 wt% CI display κ/σ from 2.71×10^{-3} to $5 \times 10^{-4} W\Omega K^{-1}$ at room temperature. With the increase in CI weight percentage, their LT value ($7.27 \times 10^{-6} W\Omega K^{-1}$) approached that of the metal. The deviation likely originates from electrical transport variations from *s*-PSWNT to CI as a major conduction channel. Nevertheless, this result suggests that the CI has a metallic nature. In addition, respective κ values of CB and dedoped *s*-SWNT are 0.1–0.2 $W mK^{-1}$ (ref. 70 and 71) and 2 $W mK^{-1}$,⁸ and the CI value (0.80 $W mK^{-1}$ for 81.9 wt% CI) lies between both. The κ value in the CI and CB also follows a defect trend, as observed in the absorption and Raman results.

4. Conclusions

As described above, we developed techniques for the removal and quantification of CI present in a PSWNT batch. PSWNT contains bundled SWNTs, CIs and a metal catalyst. We found that sonochemical dispersion of PSWNTs in chloroform

selectively disperses CI. The produced CI is an agglomerated form of edge-scrolled and defective few-layer graphene with a lateral size of 10–20 nm. UV-vis-MWIR absorption spectroscopic analysis of the CI shows that its absorption profile can be fitted by a biexponential curve and that it has an absorption cross section comparable to that of graphenes. Through a consideration of a Kataura plot and CI absorption, we were able to construct the net SWNT spectrum by using reference points in the MWIR region to subtract the CI contribution according to a given SWNT d_t distribution, which differs in different SWNT batches. The quantification method of CI was verified using SEM and AFM methodologies. The extension of absorption measurement up to far IR enables the measurement of the accurate contribution of *s*- and *m*-SWNTs. The efficacy of repetitive CI removal using a chloroform extraction was assessed and compared to the oxidative removal of CIs. The results indicate that the chloroform extraction is a much milder process. While the CI weight percentage in the SWNT film varies from 18.5 to 82%, the electrical conductivity of the SWNT varies from 4800 to 2000 S m⁻¹, whereas thermal conductivities vary from 12 to 0.8 W mK⁻¹. The morphological and optoelectronic properties of CI elucidated in this investigation provide a complete picture of an important factor governing the electronic properties of a SWNT.

Author contributions

S. J. conceived the idea, analyzed the data and wrote the manuscript. M. P. performed the FC12 synthesis, SWNT dispersion, CI enrichments and main characterizations. I. C. helped to prepare SWNT dispersions.

Conflicts of interest

There is no conflict of interest.

Acknowledgements

This research was mainly supported by the Basic Science Research Program through the National Research Foundation of Korea (NRF) funded by the Ministry of Education, Science, and Technology (2022R1A2C1006932 and 2020R1A4A1017737).

References

- 1 J. Wu, L. Xie, G. Hong, H. E. Lim, B. Thendie, Y. Miyata, H. Shinohara and H. Dai, *Nano Res.*, 2012, **5**, 388–394.
- 2 L. S. Liyanage, H. Lee, N. Patil, S. Park, S. Mitra, Z. Bao and H.-S. P. Wong, *ACS Nano*, 2012, **6**, 451–458.
- 3 G. J. Brady, Y. Joo, M.-Y. Wu, M. J. Shea, P. Gopalan and M. S. Arnold, *ACS Nano*, 2014, **8**, 11614–11621.
- 4 J. Ding, Z. Li, J. Lefebvre, F. Cheng, G. Dubey, S. Zou, P. Finnie, A. Hrdina, L. Scoles, G. P. Lopinski, C. T. Kingston, B. Simard and P. R. L. Malenfant, *Nanoscale*, 2014, **6**, 2328–2339.
- 5 M. Park, S. Kim, H. Kwon, S. Hong, S. Im and S.-Y. Ju, *ACS Appl. Mater. Interfaces*, 2016, **8**, 23270–23280.
- 6 Y. Nonoguchi, K. Ohashi, R. Kanazawa, K. Ashiba, K. Hata, T. Nakagawa, C. Adachi, T. Tanase and T. Kawai, *Sci. Rep.*, 2013, **3**, 3344.
- 7 C.-K. Mai, B. Russ, S. L. Fronk, N. Hu, M. B. Chan-Park, J. J. Urban, R. A. Segalman, M. L. Chabinyc and G. C. Bazan, *Energy Environ. Sci.*, 2015, **8**, 2341–2346.
- 8 A. D. Avery, B. H. Zhou, J. Lee, E.-S. Lee, E. M. Miller, R. Ihly, D. Wesenberg, K. S. Mistry, S. L. Guillot, B. L. Zink, Y.-H. Kim, J. L. Blackburn and A. J. Ferguson, *Nat. Energy*, 2016, **1**, 16033.
- 9 E. Kymakis and G. A. J. Amaratunga, *Appl. Phys. Lett.*, 2002, **80**, 112–114.
- 10 E. Kymakis, I. Alexandrou and G. A. J. Amaratunga, *J. Appl. Phys.*, 2003, **93**, 1764–1768.
- 11 R. V. Salvatierra, C. E. Cava, L. S. Roman and A. J. G. Zarbin, *Adv. Funct. Mater.*, 2013, **23**, 1490–1499.
- 12 C. Journet, W. K. Maser, P. Bernier, A. Loiseau, M. L. de la Chapelle, S. Lefrant, P. Deniard, R. Lee and J. E. Fischer, *Nature*, 1997, **388**, 756–758.
- 13 B. Bendjemil, E. Borowiak-Palen, A. Graff, T. Pichler, M. Guerioune, J. Fink and M. Knupfer, *Appl. Phys. A*, 2004, **78**, 311–314.
- 14 S. Yasuda, T. Hiraoka, D. N. Futaba, T. Yamada, M. Yumura and K. Hata, *Nano Lett.*, 2009, **9**, 769–773.
- 15 N. Matsumoto, G. Chen, M. Yumura, D. N. Futaba and K. Hata, *Nanoscale*, 2015, **7**, 5126–5133.
- 16 D. Vilela, A. Ansón-Casaos, M. T. Martínez, M. C. González and A. Escarpa, *Lab Chip*, 2012, **12**, 2006–2014.
- 17 Raymor, *PlasmaTubes Single-Wall Carbon Nanotubes – SWCNT | Raymor – Nanotubes for Electronics*, <https://raymor.com/our-products/plasmatubes/>, (accessed 2021/10/20, 2021).
- 18 S. Ghosh, S. M. Bachilo, R. A. Simonette, K. M. Beckingham and R. B. Weisman, *Science*, 2010, **330**, 1656.
- 19 M. S. Arnold, A. A. Green, J. F. Hulvat, S. I. Stupp and M. C. Hersam, *Nat. Nanotechnol.*, 2006, **1**, 60–65.
- 20 C. Y. Khrupin, J. A. Fagan and M. Zheng, *J. Am. Chem. Soc.*, 2013, **135**, 6822–6825.
- 21 H. Liu, D. Nishide, T. Tanaka and H. Kataura, *Nat. Commun.*, 2011, **2**, 309.
- 22 A. Nish, J.-Y. Hwang, J. Doig and R. J. Nicholas, *Nat. Nanotechnol.*, 2007, **2**, 640–646.
- 23 S. Bandow, S. Asaka, X. Zhao and Y. Ando, *Appl. Phys. A*, 1998, **67**, 23–27.
- 24 J. L. Zimmerman, R. K. Bradley, C. B. Huffman, R. H. Hauge and J. L. Margrave, *Chem. Mater.*, 2000, **12**, 1361–1366.
- 25 A. C. Dillon, T. Gennett, K. M. Jones, J. L. Alleman, P. A. Parilla and M. J. Heben, *Adv. Mater.*, 1999, **11**, 1354–1358.
- 26 Z. Li, J. Ding, P. Finnie, J. Lefebvre, F. Cheng, C. T. Kingston and P. R. L. Malenfant, *Nano Res.*, 2015, **8**, 2179–2187.
- 27 J. Wang, T. D. Nguyen, Q. Cao, Y. Wang, M. Y. C. Tan and M. B. Chan-Park, *ACS Nano*, 2016, **10**, 3222–3232.
- 28 E. Koo and S.-Y. Ju, *Carbon*, 2015, **86**, 318–324.
- 29 R. B. Weisman and S. M. Bachilo, *Nano Lett.*, 2003, **3**, 1235–1238.



- 30 K. Liu, J. Deslippe, F. Xiao, R. B. Capaz, X. Hong, S. Aloni, A. Zettl, W. Wang, X. Bai, S. G. Louie, E. Wang and F. Wang, *Nat. Nanotechnol.*, 2012, **7**, 325–329.
- 31 I.-S. Choi, M. Park, E. Koo and S.-Y. Ju, *Carbon*, 2021, **184**, 346–356.
- 32 J. Deslippe, C. D. Spataru, D. Prendergast and S. G. Louie, *Nano Lett.*, 2007, **7**, 1626–1630.
- 33 F. Wang, G. Dukovic, E. Brus Louis and F. Heinz Tony, *Science*, 2005, **308**, 838–841.
- 34 A. Reina, H. Son, L. Jiao, B. Fan, M. S. Dresselhaus, Z. Liu and J. Kong, *J. Phys. Chem. C*, 2008, **112**, 17741–17744.
- 35 M. Park and S.-Y. Ju, *Bull. Korean Chem. Soc.*, 2022, **43**, 196–200.
- 36 V. Linseis, F. Völklein, H. Reith, K. Nielsch and P. Woias, *Rev. Sci. Instrum.*, 2018, **89**, 015110.
- 37 M. Pawlyta, J.-N. Rouzaud and S. Duber, *Carbon*, 2015, **84**, 479–490.
- 38 C. T. Wirth, S. Hofmann and J. Robertson, *Diamond Relat. Mater.*, 2009, **18**, 940–945.
- 39 B. Alemán, R. Ranchal, V. Reguero, B. Mas and J. J. Vilatela, *J. Mater. Chem. C*, 2017, **5**, 5544–5550.
- 40 O. Akbarzadeh, N. A. Mohd Zabidi, Y. Abdul Wahab, N. A. Hamizi, Z. Z. Chowdhury, Z. Merican Aljunid Merican, M. Ab Rahman, S. Akhter, E. Rasouli and M. R. Johan, *Symmetry*, 2018, **10**, 572.
- 41 S. Hofmann, R. Sharma, C. Ducati, G. Du, C. Mattevi, C. Cepek, M. Cantoro, S. Pisana, A. Parvez, F. Cervantes-Sodi, A. C. Ferrari, R. Dunin-Borkowski, S. Lizzit, L. Petaccia, A. Goldoni and J. Robertson, *Nano Lett.*, 2007, **7**, 602–608.
- 42 K. L. Day and D. R. Huffman, *Nat. Phys. Sci.*, 1973, **243**, 50–51.
- 43 A. V. Naumov, S. Ghosh, D. A. Tsyboulski, S. M. Bachilo and R. B. Weisman, *ACS Nano*, 2011, **5**, 1639–1648.
- 44 A. Kuznetsova, I. Popova, J. T. Yates, M. J. Bronikowski, C. B. Huffman, J. Liu, R. E. Smalley, H. H. Hwu and J. G. Chen, *J. Am. Chem. Soc.*, 2001, **123**, 10699–10704.
- 45 J. Zhang, H. Zou, Q. Qing, Y. Yang, Q. Li, Z. Liu, X. Guo and Z. Du, *J. Phys. Chem. B*, 2003, **107**, 3712–3718.
- 46 U. J. Kim, C. A. Furtado, X. Liu, G. Chen and P. C. Eklund, *J. Am. Chem. Soc.*, 2005, **127**, 15437–15445.
- 47 K. F. Mak, J. Shan and T. F. Heinz, *Phys. Rev. Lett.*, 2011, **106**, 046401.
- 48 S. Villar-Rodil, J. I. Paredes, A. Martínez-Alonso and J. M. D. Tascón, *J. Mater. Chem.*, 2009, **19**, 3591–3593.
- 49 B. Zhao, M. E. Itkis, S. Niyogi, H. Hu, J. Zhang and R. C. Haddon, *J. Phys. Chem. B*, 2004, **108**, 8136–8141.
- 50 R. R. Nair, P. Blake, A. N. Grigorenko, K. S. Novoselov, T. J. Booth, T. Stauber, N. M. R. Peres and A. K. Geim, *Science*, 2008, **320**, 1308.
- 51 D. M. Zhigunov, G. N. Kamaev, P. K. Kashkarov and V. A. Volodin, *Appl. Phys. Lett.*, 2018, **113**, 023101.
- 52 M. S. Dresselhaus, A. Jorio, A. G. Souza Filho and R. Saito, *Philos. Trans. R. Soc., A*, 2010, **368**, 5355–5377.
- 53 L. M. Malard, M. A. Pimenta, G. Dresselhaus and M. S. Dresselhaus, *Phys. Rep.*, 2009, **473**, 51–87.
- 54 H. Kataura, Y. Kumazawa, Y. Maniwa, I. Umez, S. Suzuki, Y. Ohtsuka and Y. Achiba, *Synth. Met.*, 1999, **103**, 2555–2558.
- 55 S.-Y. Ju, W. P. Kopcha and F. Papadimitrakopoulos, *Science*, 2009, **323**, 1319–1323.
- 56 F. Wang, M. Y. Sfeir, L. Huang, X. M. H. Huang, Y. Wu, J. Kim, J. Hone, S. O'Brien, L. E. Brus and T. F. Heinz, *Phys. Rev. Lett.*, 2006, **96**, 167401.
- 57 Z. Xu, W. Lu, W. Wang, C. Gu, K. Liu, X. Bai, E. Wang and H. Dai, *Adv. Mater.*, 2008, **20**, 3615–3619.
- 58 A. K. Manna and S. K. Pati, *Nanoscale*, 2010, **2**, 1190–1195.
- 59 M. E. Itkis, D. E. Perea, S. Niyogi, S. M. Rickard, M. A. Hamon, H. Hu, B. Zhao and R. C. Haddon, *Nano Lett.*, 2003, **3**, 309–314.
- 60 K. Oi, J. Komoto, T. Kawai and Y. Nonoguchi, *Synth. Met.*, 2021, **282**, 116958.
- 61 J. Li, Y. He, Y. Han, K. Liu, J. Wang, Q. Li, S. Fan and K. Jiang, *Nano Lett.*, 2012, **12**, 4095–4101.
- 62 T. G. Ghibian and D. S. McKinney, *J. Am. Chem. Soc.*, 1951, **73**, 1431–1434.
- 63 D. Kurzydłowski, T. Chumak and J. Rogoża, *Crystals*, 2020, **10**, 920.
- 64 U. Mirsaidov, V. R. S. S. Mokkapati, D. Bhattacharya, H. Andersen, M. Bosman, B. Özyilmaz and P. Matsudaira, *Lab Chip*, 2013, **13**, 2874–2878.
- 65 X. Xie, L. Ju, X. Feng, Y. Sun, R. Zhou, K. Liu, S. Fan, Q. Li and K. Jiang, *Nano Lett.*, 2009, **9**, 2565–2570.
- 66 K. Yanagi, H. Udoguchi, S. Sagitani, Y. Oshima, T. Takenobu, H. Kataura, T. Ishida, K. Matsuda and Y. Maniwa, *ACS Nano*, 2010, **4**, 4027–4032.
- 67 B. Marinho, M. Ghislandi, E. Tkalya, C. E. Koning and G. de With, *Powder Technol.*, 2012, **221**, 351–358.
- 68 F. Lian, J. P. Llinas, Z. Li, D. Estrada and E. Pop, *Appl. Phys. Lett.*, 2016, **108**, 103101.
- 69 N. Lu, L. Li, N. Gao and M. Liu, *J. Appl. Phys.*, 2016, **120**, 195108.
- 70 W. R. Smith and G. B. Wilkes, *Ind. Eng. Chem.*, 1944, **36**, 1111–1112.
- 71 P. E. Khizhnyak, A. V. Chechetkin and A. P. Glybin, *J. Eng. Phys.*, 1979, **37**, 1073–1075.



Electronic Supplementary Information for

Quantification and Removal of the Carbonaceous Impurity in a Surfactant-Assisted Carbon Nanotube Dispersion and Its Implication to Electronic Properties

*Minsuk Park, In-Seung Choi, and Sang-Yong Ju**

Department of Chemistry, Yonsei University, 50 Yonsei-ro, Seodaemun-Gu, Seoul 03722, Republic of
Korea

* To whom correspondence should be addressed. E-mail: syju@yonsei.ac.kr

Table of Contents	S1-2
Absorption cross section calculation of monolayer graphene	S3
Defect density calculations of CI and CB.....	S4
Assignment of FT-IR bands	S5-6
Fig. S1. UV-vis-MWIR absorption spectrum of CI containing chloroform dispersion	S7
Fig. S2. Absorption spectra comparison of CI dispersion in chloroform, CB, and graphene	S7
Fig. S3. TEM and SEM images of CI dispersion in chloroform.	S8
Fig. S4. CI-subtracted absorption spectrum of FC12-PSWNT dispersion.....	S8
Fig. S5. UV-vis-FIR absorption spectra of FC12 dispersions in <i>p</i> -xylene	S9
Fig. S6. AFM height images of acetone-washed HiPco, PSWNT, and LDSWNT	S9
Fig. S7. Absorption spectra of vigorous chloroform dispersions	S10
Fig. S8. Atomic contents of PSWNT, acetone-washed PSWNT and CI.....	S10
Fig. S9. TGA thermograms	S11
Fig. S10. Overall wt. including CI/SWNT and net SWNT purity.....	S11

Fig. S11. Overlaid CI-subtracted net PSWNT spectra	S12
Fig. S12. Comparison of AFM-based number of CI per SWNT length.....	S12
Fig. S13. Configuration of prepatterned chip for σ and κ measurements.....	S13
Fig. S14. Photographs of the transferred PSWNT films on prepatterned chips	S13
Fig. S15. CI-added FC12-PSWNT dispersions	S14
Fig. S16. Thickness changes of PSWNT films on a quartz substrate by a surface profiler	S14
Cited references	S15-16

Absorption cross section calculation of monolayer graphene:

Transmission T is related to absorption cross-section (σ_{abs}) and extinction coefficient or molar absorptivity (ϵ):

$$T = \frac{I}{I_0} = 10^{-\frac{\sigma l N}{2.3}} = 10^{-\epsilon l C} = 10^{-A}$$

where I_0 and I are light intensities before and after passing the sample, l is path length, N is number of atom per a given volume, C is concentration in M. Since unit area of graphene unit cell has two carbon atoms per 0.052 nm^2 , we know $N \times l$ value (*i.e.*, $2/(0.052 \text{ nm}^2)$) and l is thickness of monolayer graphene (*i.e.*, 0.34 nm). In addition, T of monolayer graphene at 550 nm is 97.7% .^{S1}

Rearrangement of the above equation and plugging each value in the equation gives rise to σ_{abs} of monolayer graphene at 550 nm :

$$\begin{aligned}\sigma_{\text{abs}} &= \frac{-2.3 \times \log T}{lN} = \frac{(-2.3) \times (-0.01)}{0.34 \text{ nm} \times \left[\frac{2}{0.052 \text{ nm}^2 \times 0.34 \text{ nm}} \right]} \\ &= 5.9 \times 10^{-18} \text{ cm}^2\end{aligned}$$

Defect density calculations of CI and CB:

The defect density, and nature of defects can be estimated by using intensity of D band (I_D) and intensity of G band (I_G).^{S2} The I_D/I_G can be utilized to express the defect density (L_D , in nm, average distance between two defects)^{S2} by using following equation (the modified Tuinstra-Koenig relation),

$$I_D / I_G = C_A \times \pi(r_A^2 - r_S^2) / L_D^2$$

where C_A is the dimensionless wavelength-dependent parameter which is given by $(160 \pm 48) \text{ eV}^4 \times E_L^{-4}$, and r_A and r_S are radius of the area surrounding point defect, and of structurally disordered area, respectively, and E_L is laser energy in eV.^{S2} The I_D/I_G ratio is 0.267 for CI, and 0.87 for CB^{S3}. For both cases, laser wavelength is 532 nm 514.5 nm, respectively, and those values give rise to C_A of 5.4 ± 1.6 and 4.7 ± 1.4 , respectively. Considering previously determined r_A and r_S values (*i.e.*, 3.1 and 1 nm),^{S2} the estimated average distance (L_D) between defects of CI and CB were approximately 23 and 12 nm. This result indicates that CI possesses higher crystalline graphene than CB.

Assignment of FT-IR bands:

Combined absorption spectra from UV-vis-MIR and FT-IR measurements reveal profound vibrational bands from solvents (*i.e.*, *p*-xylene, chloroform, and water), FC12, and oxygenated defects of nanocarbons.

In the case of CI dispersions in chloroform (*i.e.*, Fig. S1 for PSWNT-derived dispersion and Fig. S7 for HiPco- and LDSWNT-derived dispersions), vibrational bands originate from both oxygenated defects on CI and chloroform. 1710, 1604, and 1362 cm^{-1} are observed as strong, weak, and medium intensities and those are assigned to symmetric C=O stretch of carboxylic acid or ketone group ($\nu_{\text{s, C=O}}$), symmetric C=C stretch of aromatic groups ($\nu_{\text{s, C=C}}$), and interaction between O-H bending ($\delta_{\text{O-H}}$) and C-O stretching in phenolic group ($\nu_{\text{C-O}}$), respectively. Those are attributed to oxygenated defects (carboxylic acid, phenol, *etc*) which are also observed in the case of SWNT.^{S4-S6} In addition, 3039, 2400, 1519, and 1423 cm^{-1} which are chloroform-related band appear as noisy features due to absorption saturation as solvent. 3039 cm^{-1} band stems from symmetric C-H stretching ($\nu_{\text{s, C-H}}$). Other bands originate from either overtones [2400 cm^{-1} for *ca.* $2 \times$ C-H symmetric bending ($\delta_{\text{s, C-H}}$), 1519 cm^{-1} for *ca.* $2 \times$ C-Cl asymmetric stretching ($\nu_{\text{as, C-Cl}}$)] or combination band [1423 cm^{-1} for symmetric C-Cl stretching ($\nu_{\text{s, C-Cl}}$) + asymmetric C-Cl stretching ($\nu_{\text{as, C-Cl}}$)]. Those are in excellent agreement with the literatures^{S7, S8} Moreover, 3704 cm^{-1} band was assigned to symmetric and asymmetric O-H stretches ($\nu_{\text{s, O-H}}$ and $\nu_{\text{as, O-H}}$) of residual water.^{S9} Noisy 2346 cm^{-1} band was associated with asymmetric C=O stretching ($\nu_{\text{as, C=O}}$) of CO₂.^{S10} Weak 1474 cm^{-1} band is tentatively assigned to asymmetric bending of C-H ($\delta_{\text{s, C-H}}$) originating from residue of cleaning solvent (*e.g.*, acetone).

For the cases of FC12-SWNT dispersions (Fig. 3B to 3D and IR extensions (Fig. S5A to S5C) which are the spectra of FC12-HiPco, FC12-PSWNT, and FC12-LDSWNT in *p*-xylene, respectively), more complicated vibrational bands were observed. Vibrational bands consist of the contribution from FC12, oxygenated nanocarbon defects and solvents (*i.e.*, *p*-xylene and residual water). 3409, 3333, and 1705 cm^{-1} originate from FC12 moiety. The former two bands are attributed to N-H stretches of secondary

amide ($\nu_{\text{s, R2N-H}}$) in the uracil moiety of FC12.^{S11, S12} The latter band is corresponding to the $\text{C}_4=\text{O}$ stretching of FC12 ($\nu_{\text{C4=O}}$).^{S11, S13} Those bands overlaps with bands (*e.g.*, 1717 and 1689 cm^{-1}) from oxygenated defects (carboxylic acid, quinone, *etc*) of CI and SWNT.^{S4-S6} 3704 cm^{-1} band is associated with symmetric and asymmetric O-H stretching ($\nu_{\text{s, O-H}}$ and $\nu_{\text{as, O-H}}$) of residual water.^{S9} The other noisy features at 3020, 2923, 2730, 1890, 1783, 1630, 1516, 1454, 1043, 795, and 484 cm^{-1} bands originate from *p*-xylene. 3020 (ring C-H stretching, $\nu_{\text{C-H}}$), 2923 (symmetric methyl C-H stretching, $\nu_{\text{s, C-H of methyl}}$), 1516 (ring C=C stretching, $\nu_{\text{s, C=C of ring}}$), 1454 (methyl scissoring, $\delta_{\text{s, methyl}}$), 1043 (methyl rocking, ρ_{methyl}), 795 (symmetric ring C-H bending, $\delta_{\text{s, C-H of ring}}$), and 484 cm^{-1} (ring C-C=C bending, $\delta_{\text{C-C=C of ring}}$) bands are fundamental vibrations. Other bands are associated from combination bands such as 2730 (in-phase and out-of-phase methyl umbrella), 1890 (ring C=C stretching ($\nu_{\text{C=C}}$) and methyl C-C bending, ($\delta_{\text{C-C of methyl}}$)), 1783 (methyl C-C bending ($\delta_{\text{C-C of methyl}}$) and methyl asymmetric H-C-H bending ($\delta_{\text{as, H-C-H of methyl}}$)) and 1630 cm^{-1} (ring C-H bending ($\delta_{\text{C-H of ring}}$) and symmetric ring C-H bending ($\delta_{\text{s, C-H of ring}}$)).^{S14}

Fig. S1. UV-vis-MWIR absorption spectrum of CI containing chloroform dispersion of as-supplied PSWNT. UV-vis-MWIR spectrum (black) was stitched with FT-IR spectrum (blue). Extended biexponential curve to 8000 nm (red) was well agreed with measured curve.

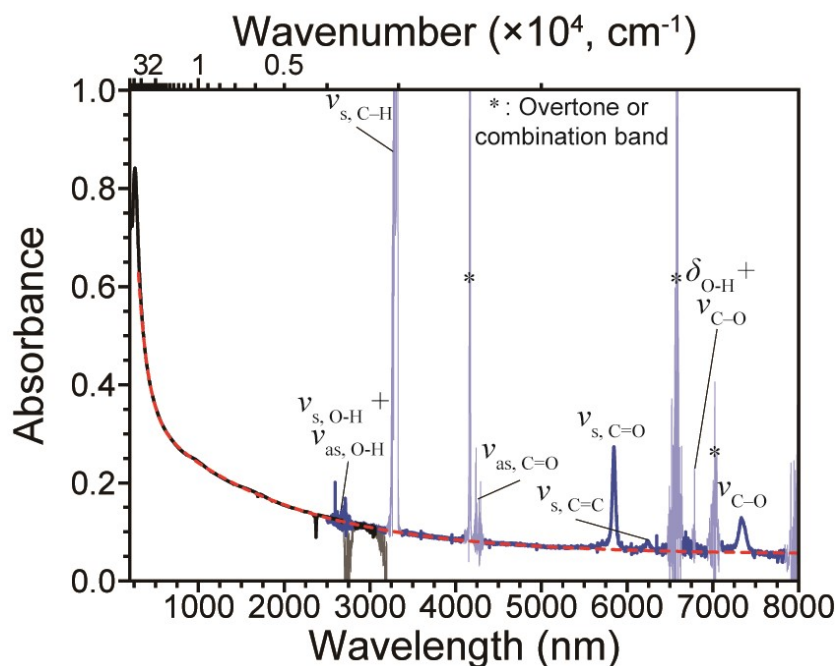


Fig. S2. Absorption spectra comparison of (A) CI dispersion in chloroform, (B) CB, and (C) graphene. CB spectra and graphene spectra was adapted with permission from the ref. ^{S15} and ^{S16}, respectively. Copyright 2004 American Chemical Society. Copyright 2011 American Physical Society.

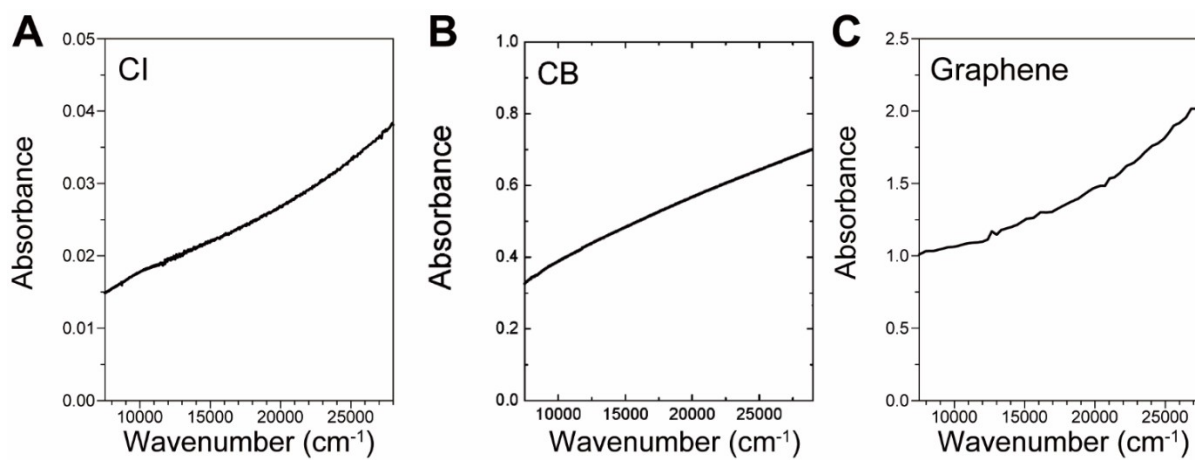


Fig. S3. TEM and SEM images of CI dispersion in chloroform. (A) TEM images of CI enriched area and (B) metal catalyst containing area. (C-D) SEM images of concentrated CI enriched sample. A small amount of SWNT is embedded between the CIs.

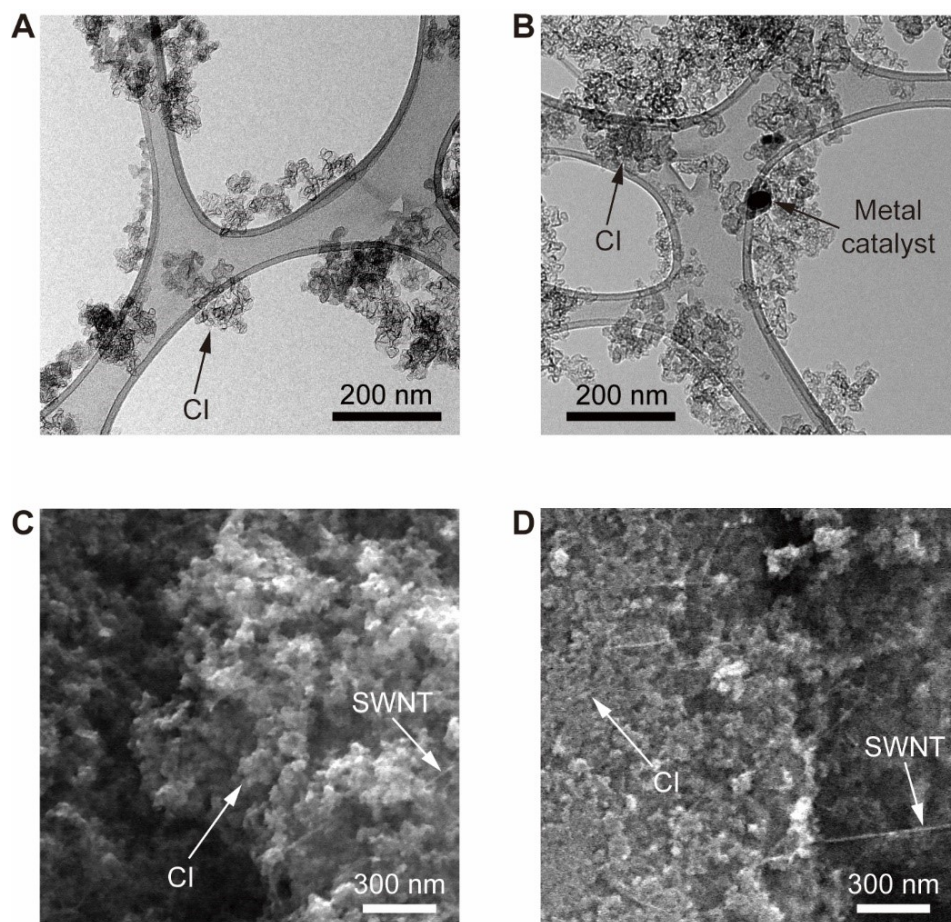


Fig. S4. CI-subtracted absorption spectrum of FC12-PSWNT dispersion. Absorption near 2700 nm region stems from symmetric and asymmetric stretches of O-H present in residual water.

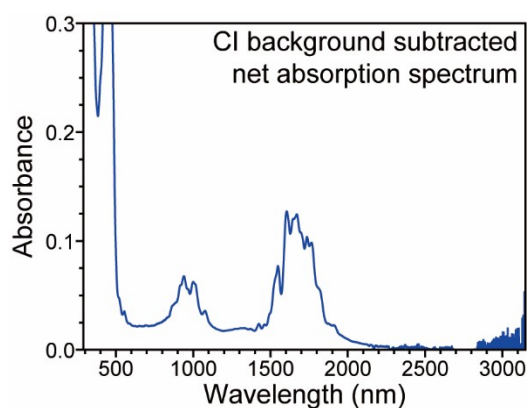


Fig. S7. Absorption spectra of vigorous chloroform dispersions from (A) HiPco and (B) LDSWNT samples. Inset: corresponding AFM height images. No SWNT were found in each inset.

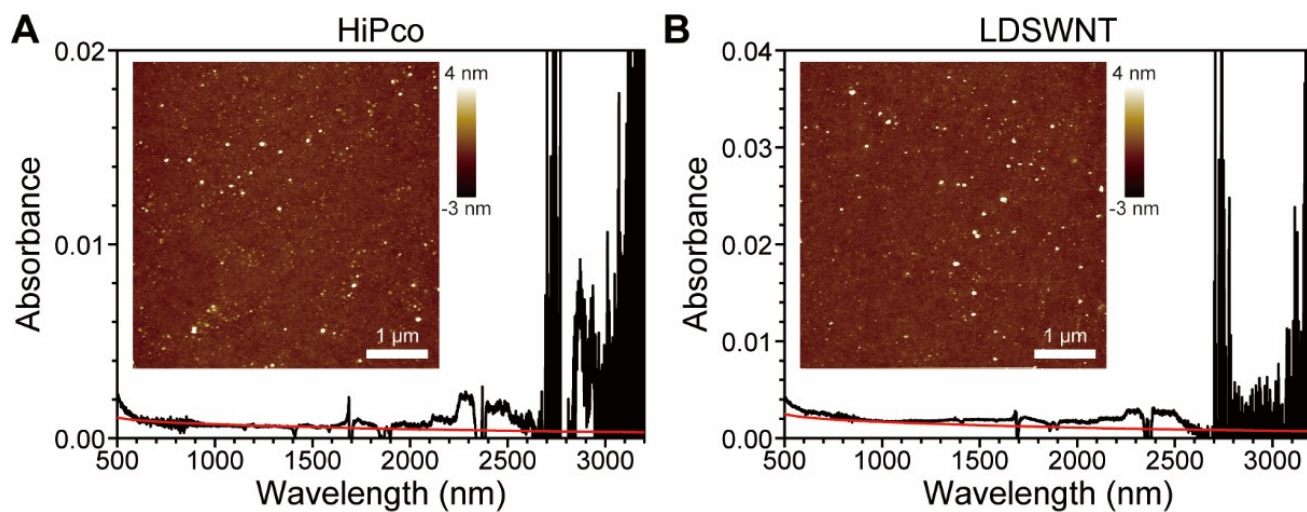


Fig. S8. Atomic contents of PSWNT, acetone-washed PSWNT and CI from the dispersions. XPS spectra of (A) PSWNT, (B) acetone-washed PSWNT, and (C) CI samples from the dispersion. (D) Comparison of atomic % present in both samples.

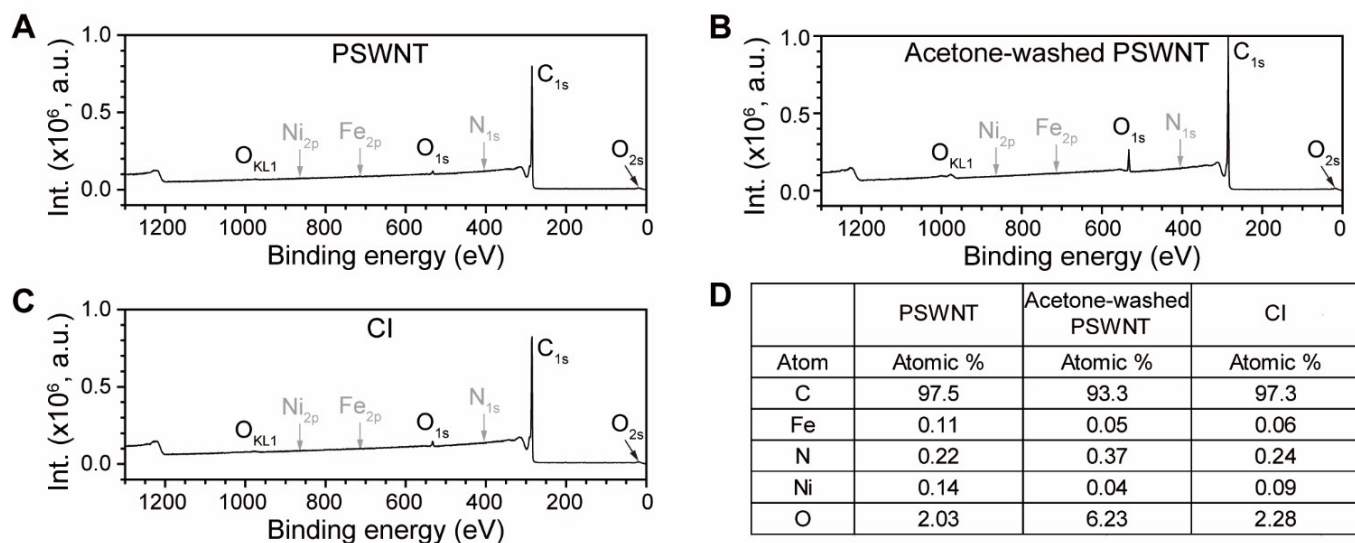


Fig. S9. TGA thermograms of (A) PSWNT, (B) CI from CI dispersion in chloroform, (C) acetone-washed PSWNT. (D) Fitting of PSWNT trace with CI trace and acetone-washed PSWNT trace.

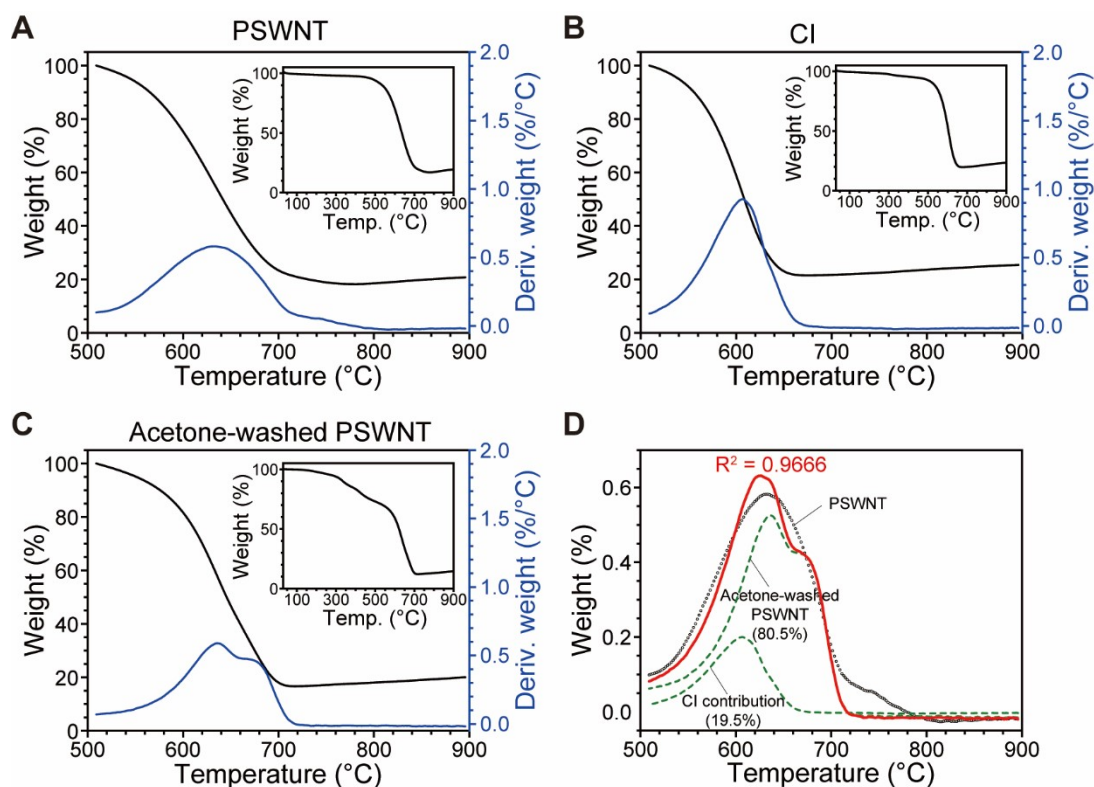


Fig. S10. Overall wt. including CI/SWNT and net SWNT purity according to repetitive chloroform extraction cycles. Error bars in overall wt. denotes the minimum digit of microbalance.

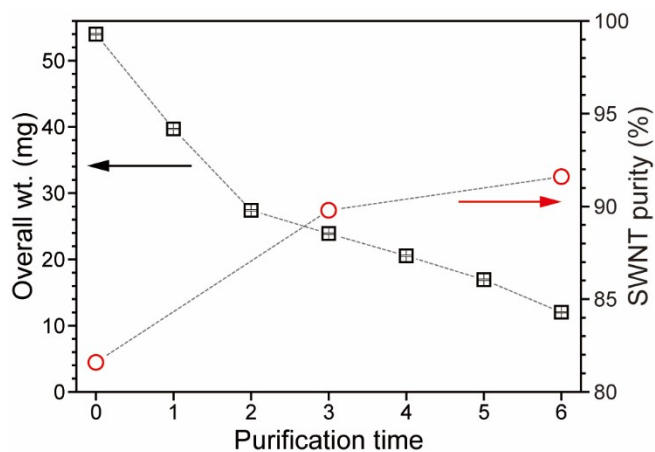


Fig. S11. Overlaid CI-subtracted net PSWNT spectra from repetitive chloroform extraction samples such as without chloroform extraction (black), 3 times chloroform extraction (red), and 6 times chloroform extraction (blue) samples.

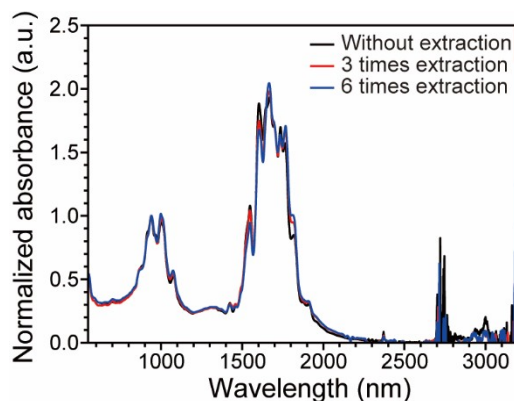


Fig. S12. Comparison of AFM-based number of CI per SWNT length according to number of chloroform extraction. Dashed line denotes the number of CI per SWNT length from AFM topography of SPSWNT dispersion. Error bars were obtained from standard deviation using 4 topographies per each sample, and number of CI per SWNT length value of each topography are drawn in grey circle.

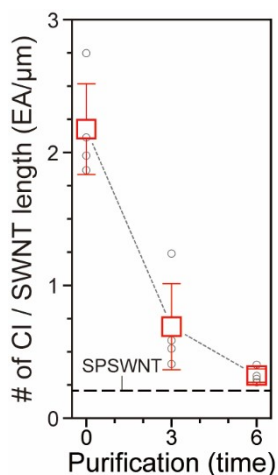


Fig. S13. Configuration of prepatterned chip for σ and κ measurements. (A) Photograph of whole prepatterned chip. Dashed box denotes a designated area for materials to be transferred. (B) Low-magnification optical microscope (OM) image of area measuring thermal properties. (C) Zoomed-in OM image of κ measuring circuits on Si_3N_4 membrane. (D) Cross-sectional schematic of κ measuring circuits in prepatterned chip. Note that Pt heating wire suspended on a Si_3N_4 membrane was used to minimize κ of materials other than sample.^{S17}

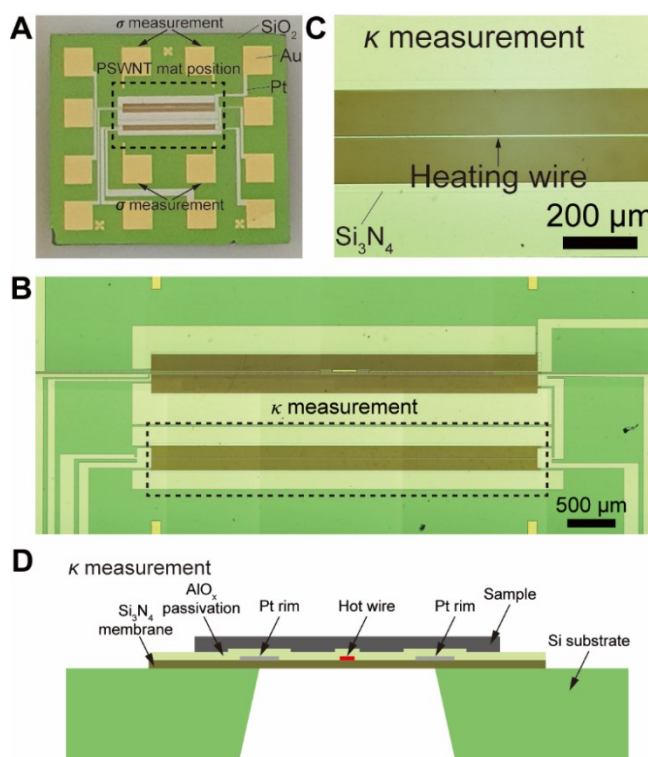


Fig. S14. Photographs of the transferred PSWNT films on prepatterned chips with varying CI wt.%. (A) 18.5, (B) 31.2, (C) 53.1, and (D) 69.3.

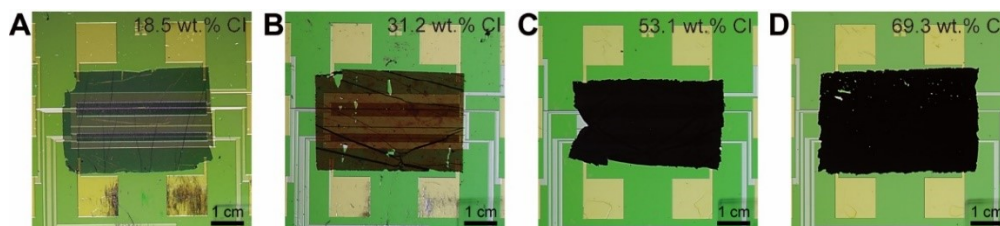


Fig. S15. CI-added FC12-PSWNT dispersion. UV-vis-MIR absorption spectra of FC12-PSWNT dispersions in *p*-xylene with varying CI amount. Inset: photograph of the dispersions.

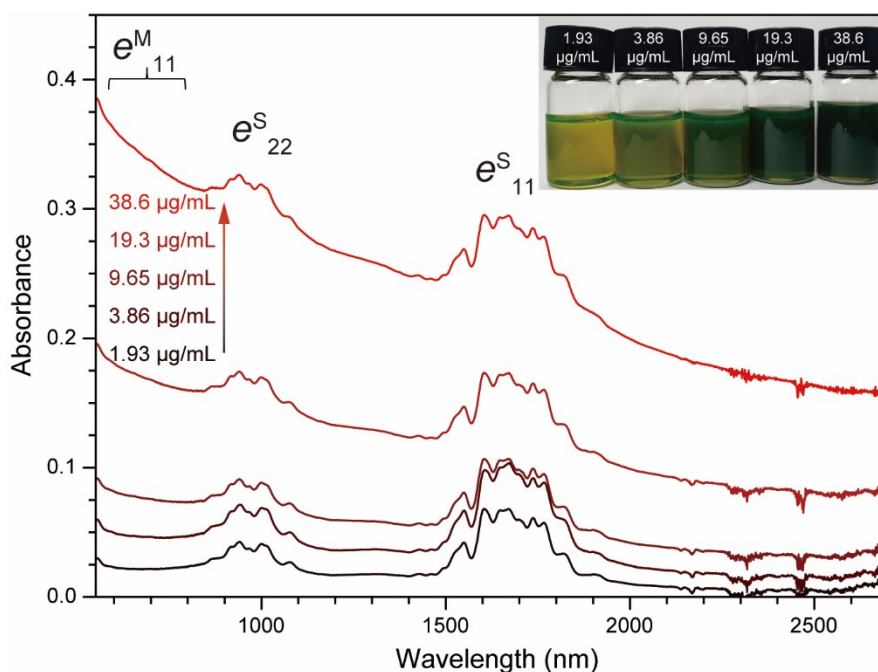
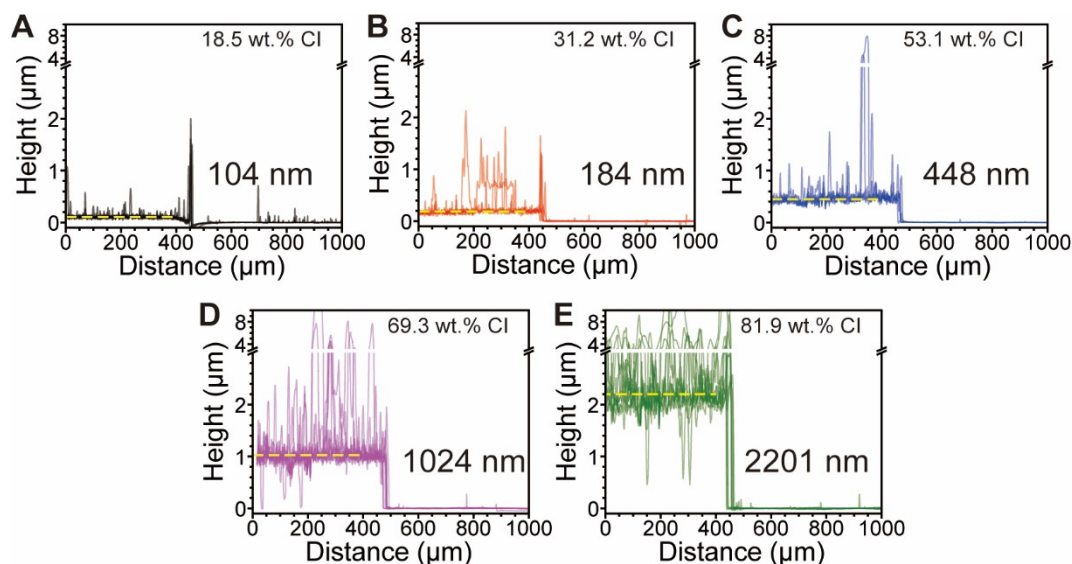


Fig. S16. Thickness changes of PSWNT film on a quartz substrate by a surface profiler. Height profiles of PSWNT films with CI whose CI wt. % are (A) 18.5, (B) 31.2, (C) 53.1, (D) 69.3, and (E) 81.9. Average thickness (dashed line) was obtained from basal plane thickness from 5 different measurements.



Cited references

- S1. R. R. Nair, P. Blake, A. N. Grigorenko, K. S. Novoselov, T. J. Booth, T. Stauber, N. M. R. Peres and A. K. Geim, *Science*, 2008, **320**, 1308-1308.
- S2. L. G. Cançado, A. Jorio, E. H. M. Ferreira, F. Stavale, C. A. Achete, R. B. Capaz, M. V. O. Moutinho, A. Lombardo, T. S. Kulmala and A. C. Ferrari, *Nano Lett.*, 2011, **11**, 3190-3196.
- S3. M. Pawlyta, J.-N. Rouzaud and S. Duber, *Carbon*, 2015, **84**, 479-490.
- S4. A. Kuznetsova, I. Popova, J. T. Yates, M. J. Bronikowski, C. B. Huffman, J. Liu, R. E. Smalley, H. H. Hwu and J. G. Chen, *J. Am. Chem. Soc.*, 2001, **123**, 10699-10704.
- S5. J. Zhang, H. Zou, Q. Qing, Y. Yang, Q. Li, Z. Liu, X. Guo and Z. Du, *J. Phys. Chem. B*, 2003, **107**, 3712-3718.
- S6. U. J. Kim, C. A. Furtado, X. Liu, G. Chen and P. C. Eklund, *J. Am. Chem. Soc.*, 2005, **127**, 15437-15445.
- S7. T. G. Gibian and D. S. McKinney, *J. Am. Chem. Soc.*, 1951, **73**, 1431-1434.
- S8. D. Kurzydłowski, T. Chumak and J. Rogoża, *Crystals*, 2020, **10**.
- S9. J. E. Bertie, M. K. Ahmed and H. H. Eysel, *J. Phys. Chem.*, 1989, **93**, 2210-2218.
- S10. X. Zhang and S. P. Sander, *J. Phys. Chem. A*, 2011, **115**, 9854-9860.
- S11. M. Abe and Y. Kyogoku, *Spectroc. Acta A*, 1987, **43**, 1027-1037.
- S12. S.-Y. Ju and F. Papadimitrakopoulos, *J. Am. Chem. Soc.*, 2008, **130**, 655-664.
- S13. M. P. Kabir, Y. Orozco-Gonzalez, G. Hastings and S. Gozem, *Spectroc. Acta A*, 2021, **262**, 120110.
- S14. R. Lindenmaier, N. K. Scharko, R. G. Tonkyn, K. T. Nguyen, S. D. Williams and T. J. Johnson, *J. Mol. Struct.*, 2017, **1149**, 332-351.
- S15. B. Zhao, M. E. Itkis, S. Niyogi, H. Hu, J. Zhang and R. C. Haddon, *J. Phys. Chem. B*, 2004, **108**, 8136-8141.
- S16. K. F. Mak, J. Shan and T. F. Heinz, *Phys. Rev. Lett.*, 2011, **106**, 046401.

- S17. Linseis, TFA - Thin Film Analyzer from LINSEIS, <https://www.linseis.com/en/products/thin-film-analyzer/tfa-thin-film-analyzer/#description>, (accessed 2021/10/20, 2021).